



ispGDX®160V/VA Device Datasheet

June 2010

Select Devices Discontinued!

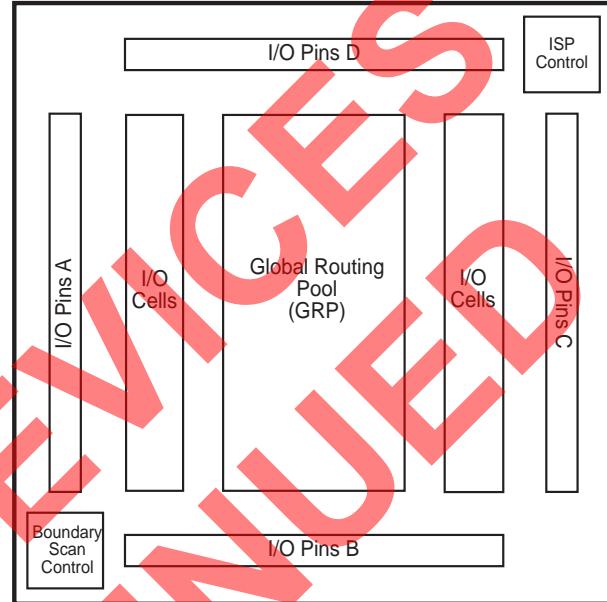
Product Change Notification (PCN) #09-10 has been issued to discontinue select devices in this data sheet.

The original datasheet pages have not been modified and do not reflect those changes. Please refer to the table below for reference PCN and current product status.

Product Line	Ordering Part Number	Product Status	Reference PCN	
ispGDX160V	ispGDX160V-5B272	Discontinued	PCN#09-10	
	ispGDX160V-7B272			
	ispGDX160V-5B208	Active / Orderable		
	ispGDX160V-7B208			
	ispGDX160V-5Q208			
	ispGDX160V-7Q208			
	ispGDX160V-7Q208I			
ispGDX160VA	ispGDX160VA-3B272	Discontinued	PCN#09-10	
	ispGDX160VA-5B272			
	ispGDX160VA-7B272			
	ispGDX160VA-5B272I			
	ispGDX160VA-7B272I			
	ispGDX160VA-9B272I			
	ispGDX160VA-3Q208	Active / Orderable		
	ispGDX160VA-5Q208			
	ispGDX160VA-7Q208			
	ispGDX160VA-5Q208I			
	ispGDX160VA-7Q208I			
	ispGDX160VA-9Q208I			
	ispGDX160VA-3B208			
	ispGDX160VA-3BN208			
	ispGDX160VA-5B208			
	ispGDX160VA-5BN208			
	ispGDX160VA-7B208			
	ispGDX160VA-7BN208			
	ispGDX160VA-5B208I			
	ispGDX160VA-5BN208I			
	ispGDX160VA-7B208I			
	ispGDX160VA-7BN208I			
	ispGDX160VA-9B208I			
	ispGDX160VA-9BN208I			

- IN-SYSTEM PROGRAMMABLE GENERIC DIGITAL CROSSPOINT FAMILY
 - Advanced Architecture Addresses Programmable PCB Interconnect, Bus Interface Integration and Jumper/Switch Replacement
 - “Any Input to Any Output” Routing
 - Fixed HIGH or LOW Output Option for Jumper/DIP Switch Emulation
 - Space-Saving PQFP and BGA Packaging
 - Dedicated IEEE 1149.1-Compliant Boundary Scan Test
- HIGH PERFORMANCE E²CMOS® TECHNOLOGY
 - 3.3V Core Power Supply
 - 3.5ns Input-to-Output/3.5ns Clock-to-Output Delay*
 - 250MHz Maximum Clock Frequency*
 - TTL/3.3V/2.5V Compatible Input Thresholds and Output Levels (Individually Programmable)*
 - Low-Power: 16.5mA Quiescent Icc*
 - 24mA I_{OL} Drive with Programmable Slew Rate Control Option
 - PCI Compatible Drive Capability*
 - Schmitt Trigger Inputs for Noise Immunity
 - Electrically Erasable and Reprogrammable
 - Non-Volatile E²CMOS Technology
- ispGDXV OFFERS THE FOLLOWING ADVANTAGES
 - 3.3V In-System Programmable Using Boundary Scan Test Access Port (TAP)
 - Change Interconnects in Seconds
- FLEXIBLE ARCHITECTURE
 - Combinatorial/Latched/Registered Inputs or Outputs
 - Individual I/O Tri-state Control with Polarity Control
 - Dedicated Clock/Clock Enable Input Pins (four) or Programmable Clocks/Clock Enables from I/O Pins (40)
 - Single Level 4:1 Dynamic Path Selection ($T_{pd} = 3.5\text{ns}$)
 - Programmable Wide-MUX Cascade Feature Supports up to 16:1 MUX
 - Programmable Pull-ups, Bus Hold Latch and Open Drain on I/O Pins
 - Outputs Tri-state During Power-up (“Live Insertion” Friendly)
- LEAD-FREE PACKAGE OPTIONS

* “VA” Version Only



The ispGDXV/VA architecture provides a family of fast, flexible programmable devices to address a variety of system-level digital signal routing and interface requirements including:

- Multi-Port Multiprocessor Interfaces
- Wide Data and Address Bus Multiplexing (e.g. 16:1 High-Speed Bus MUX)
- Programmable Control Signal Routing (e.g. Interrupts, DMAREQs, etc.)
- Board-Level PCB Signal Routing for Prototyping or Programmable Bus Interfaces

The devices feature fast operation, with input-to-output signal delays (T_{pd}) of 3.5ns and clock-to-output delays of 3.5ns.

The architecture of the devices consists of a series of programmable I/O cells interconnected by a Global Routing Pool (GRP). All I/O pin inputs enter the GRP directly or are registered or latched so they can be routed to the required I/O outputs. I/O pin inputs are defined as four sets (A,B,C,D) which have access to the four MUX inputs

found in each I/O cell. Each output has individual, programmable I/O tri-state control (OE), output latch clock (CLK), clock enable (CLKEN), and two multiplexer control (MUX0 and MUX1) inputs. Polarity for these signals is programmable for each I/O cell. The MUX0 and MUX1 inputs control a fast 4:1 MUX, allowing dynamic selection of up to four signal sources for a given output. A wider 16:1 MUX can be implemented with the MUX expander feature of each I/O and a propagation delay increase of 2.0ns. OE, CLK, CLKEN, and MUX0 and MUX1 inputs can be driven directly from selected sets of I/O pins. Optional dedicated clock input pins give minimum clock-to-output delays. CLK and CLKEN share the same set of I/O pins. CLKEN disables the register clock when CLKEN = 0.

Through in-system programming, connections between I/O pins and architectural features (latched or registered inputs or outputs, output enable control, etc.) can be defined. In keeping with its data path application focus, the ispGDXV devices contain no programmable logic arrays. All input pins include Schmitt trigger buffers for noise immunity. These connections are programmed into the device using non-volatile E²CMOS technology. Non-volatile technology means the device configuration is saved even when the power is removed from the device.

Table 1. ispGDXV Family Members

	ispGDXVA Device		
	ispGDX80VA	ispGDX160VA	ispGDX240VA
I/O Pins	80	160	240
I/O-OE Inputs*	20	40	60
I/O-CLK / CLKEN Inputs*	20	40	60
I/O-MUXsel1 Inputs*	20	40	60
I/O-MUXsel2 Inputs*	20	40	60
Dedicated Clock Pins**	2	4	4
EPEN	1	1	1
TOE	1	1	1
BSCAN Interface	4	4	4
RESET	1	1	1
Pin Count/Package	100-Pin TQFP	208-Pin PQFP 208-Ball fpBGA 272-Ball BGA	388-Ball fpBGA

* The CLK/CLK_EN, OE, MUX0 and MUX1 terminals on each I/O cell can each be assigned to 25% of the I/Os.

** Global clock pins Y0, Y1, Y2 and Y3 are multiplexed with CLKEN0, CLKEN1, CLKEN2 and CLKEN3 respectively in all devices.

In addition, there are no pin-to-pin routing constraints for 1:1 or 1:n signal routing. That is, *any* I/O pin configured as an input can drive one or more I/O pins configured as outputs.

The device pins also have the ability to set outputs to fixed HIGH or LOW logic levels (Jumper or DIP Switch mode). Device outputs are specified for 24mA sink and 12mA source current (at JEDEC LVTTL levels) and can be tied together in parallel for greater drive. On the ispGDXVA, each I/O pin is individually programmable for 3.3V or 2.5V output levels as described later. Programmable output slew rate control can be defined independently for each I/O pin to reduce overall ground bounce and switching noise.

All I/O pins are equipped with IEEE1149.1-compliant Boundary Scan Test circuitry for enhanced testability. In addition, in-system programming is supported through the Test Access Port via a special set of private commands.

The ispGDXV I/Os are designed to withstand “live insertion” system environments. The I/O buffers are disabled during power-up and power-down cycles. When designing for “live insertion,” absolute maximum rating conditions for the Vcc and I/O pins must still be met.

The *ispGDXV/VA* architecture is different from traditional PLD architectures, in keeping with its unique application focus. The block diagram is shown below. The programmable interconnect consists of a single Global Routing Pool (GRP). Unlike *ispLSI®* devices, there are no programmable logic arrays on the device. Control signals for OEs, Clocks/Clock Enables and MUX Controls must come from designated sets of I/O pins. The polarity of these signals can be independently programmed in each I/O cell.

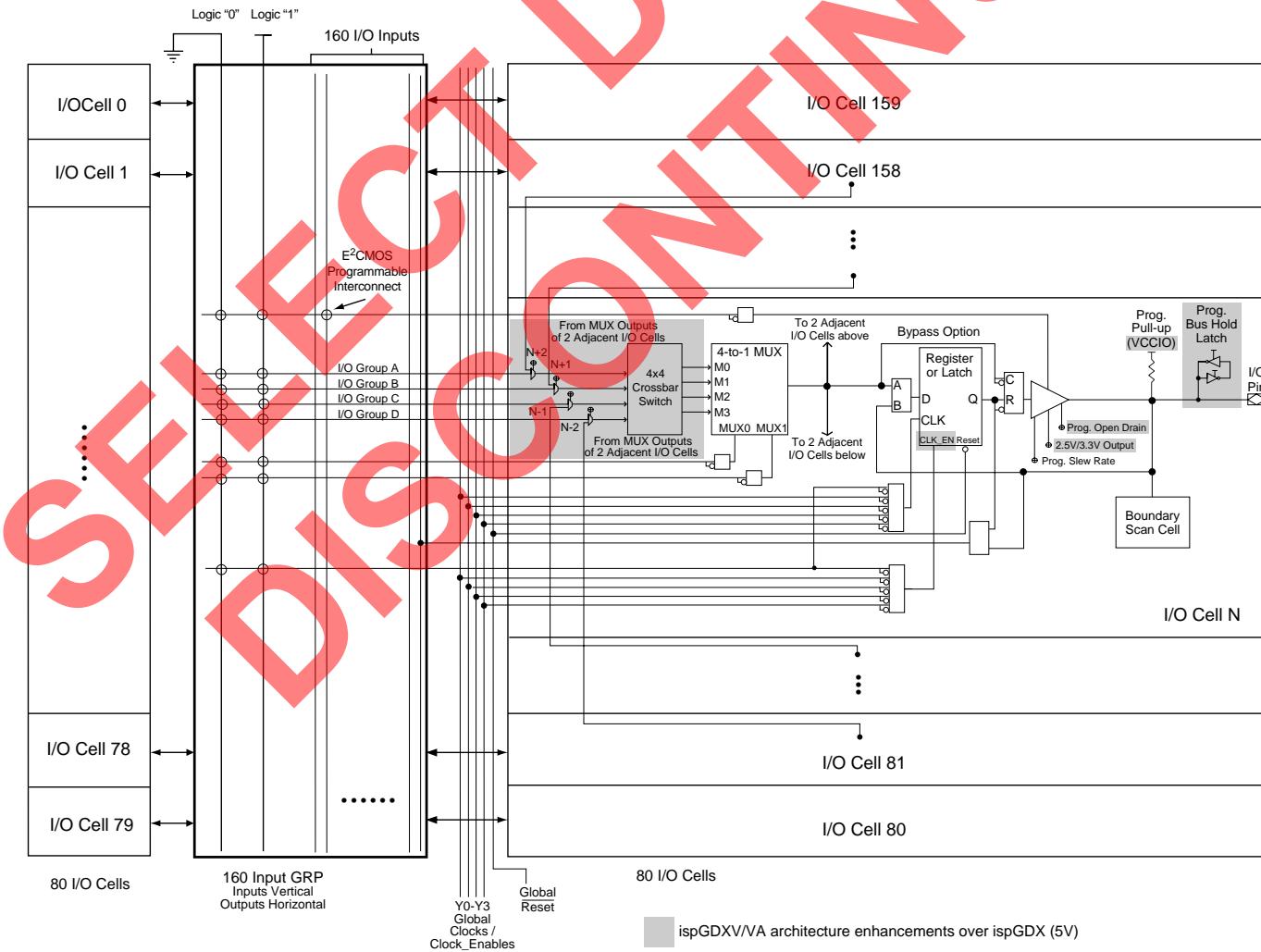
Each I/O cell drives a unique pin. The OE control for each I/O pin is independent and may be driven via the GRP by one of the designated I/O pins (I/O-OE set). The I/O-OE set consists of 25% of the total I/O pins. Boundary Scan test is supported by dedicated registers at each I/O pin. In-system programming is accomplished through the standard Boundary Scan protocol.

The various I/O pin sets are also shown in the block diagram below. The A, B, C, and D I/O pins are grouped together with one group per side.

I/O Architecture

Each I/O cell contains a 4:1 dynamic MUX controlled by two select lines as well as a 4x4 crossbar switch controlled by software for increased routing flexibility (Figure 1). The four data inputs to the MUX (called M0, M1, M2, and M3) come from I/O signals in the GRP and/or adjacent I/O cells. Each MUX data input can access one quarter of the total I/Os. For example, in a 160 I/O *ispGDXV*, each data input can connect to one of 40 I/O pins. MUX0 and MUX1 can be driven by designated I/O pins called MUXsel1 and MUXsel2. Each MUXsel input covers 25% of the total I/O pins (e.g. 40 out of 160). MUX0 and MUX1 can be driven from either MUXsel1 or MUXsel2.

Figure 1. *ispGDXV/VA* I/O Cell and GRP Detail (160 I/O Device)



I/O MUX Operation

MUX1	MUX0	Data Input Selected
0	0	M0
0	1	M1
1	1	M2
1	0	M3

Flexible mapping of $MUXsel_x$ to MUX_x allows the user to change the MUX select assignment after the ispGDXV/VA device has been soldered to the board. Figure 1 shows that the I/O cell can accept (by programming the appropriate fuses) inputs from the MUX outputs of four adjacent I/O cells, two above and two below. This enables cascading of the MUXes to enable wider (up to 16:1) MUX implementations.

The I/O cell also includes a programmable flow-through latch or register that can be placed in the input or output path and bypassed for combinatorial outputs. As shown in Figure 1, when the input control MUX of the register/latch selects the "A" path, the register/latch gets its inputs from the 4:1 MUX and drives the I/O output. When selecting the "B" path, the register/latch is directly driven by the I/O input while its output feeds the GRP. The programmable polarity Clock to the latch or register can be connected to any I/O in the I/O-CLK/CLKEN set (one-quarter of total I/Os) or to one of the dedicated clock input pins (Y_x). The programmable polarity Clock Enable input to the register can be programmed to connect to any of the I/O-CLK/CLKEN input pin set or to the global clock enable inputs ($CLKEN_x$). Use of the dedicated clock inputs gives minimum clock-to-output delays and minimizes delay variation with fanout. Combinatorial output mode may be implemented by a dedicated architecture bit and bypass MUX. I/O cell output polarity can be programmed as active high or active low.

The ispGDXV/VA allows adjacent I/O cell MUXes to be cascaded to form wider input MUXes (up to 16 x 1) without incurring an additional full T_{pd} penalty. However, there are certain dependencies on the locality of the adjacent MUXes when used along with direct MUX inputs.

Adjacent I/O Cells

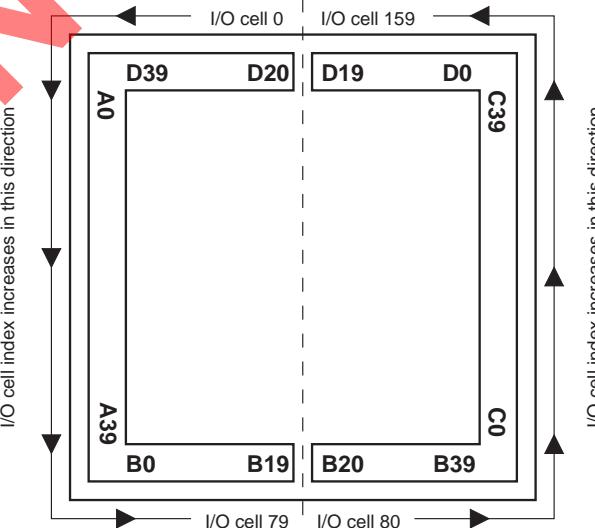
Expansion inputs $MUXOUT[n-2]$, $MUXOUT[n-1]$, $MUXOUT[n+1]$, and $MUXOUT[n+2]$ are fuse-selectable for each I/O cell MUX. These expansion inputs share the same path as the standard A, B, C and D MUX inputs, and

allow adjacent I/O cell outputs to be directly connected without passing through the global routing pool. The relationship between the $[N+i]$ adjacent cells and A, B, C and D inputs will vary depending on where the I/O cell is located on the physical die. The I/O cells can be grouped into "normal" and "reflected" I/O cells or I/O "hemispheres." These are defined as:

Device	Normal I/O Cells	Reflected I/O Cells
ispGDX80VA	TBA	TBA
ispGDX160V/VA	B19-B0, A39-A20, A19-A0, D39-D20	B20-B39, C0-C19, C20-C39, D0-D19
ispGDX240VA	TBA	TBA

Table 2 shows the relationship between adjacent I/O cells as well as their relationship to direct MUX inputs. Note that the MUX expansion is circular and that I/O cell B20, for example, draws on I/Os B19 and B18, as well as B21 and B22, even though they are in different hemispheres of the physical die. Table 2 shows some typical cases and all boundary cases. All other cells can be extrapolated from the pattern shown in the table.

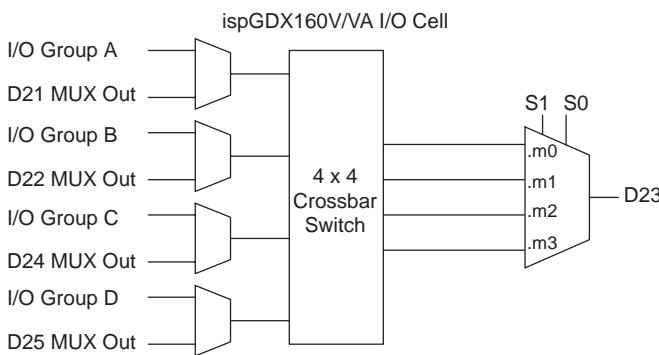
Figure 2. I/O Hemisphere Configuration of *ispGDX160V/VA*



Direct and Expander Input Routing

Table 2 also illustrates the routing of MUX direct inputs that are accessible when using adjacent I/O cells as inputs. Take I/O cell D23 as an example, which is also shown in Figure 3.

Figure 3. Adjacent I/O Cells vs. Direct Input Path for ispGDX160V/VA, I/O D23



It can be seen from Figure 3 that if the D21 adjacent I/O cell is used, the I/O group "A" input is no longer available as a direct MUX input.

The ispGDXV/VA can implement MUXes up to 16 bits wide in a single level of logic, but care must be taken when combining adjacent I/O cell outputs with direct MUX inputs. Any particular combination of adjacent I/O cells as MUX inputs will dictate what I/O groups (A, B, C or D) can be routed to the remaining inputs. By properly choosing the adjacent I/O cells, all of the MUX inputs can be utilized.

Table 2. Adjacent I/O Cells (Mapping of ispGDX160V/VA)

	Data A/ MUXOUT	Data B/ MUXOUT	Data C/ MUXOUT	Data D/ MUXOUT
Reflected I/O Cells	B20	B22	B21	B19
	B21	B23	B22	B19
	B22	B24	B23	B21
	B23	B25	B24	B22
	D16	D18	D17	D15
	D17	D19	D18	D16
	D18	D20	D19	D17
	D19	D21	D20	D18
Normal I/O Cells	D20	D18	D19	D21
	D21	D19	D20	D22
	D22	D20	D21	D23
	D23	D21	D22	D24
	B16	B14	B15	B17
	B17	B15	B16	B18
	B18	B16	B17	B19
	B19	B17	B18	B20
				B21

Slew Rate Control

All output buffers contain a programmable slew rate control that provides software-selectable slew rate options.

Open Drain Control

All output buffers provide a programmable Open-Drain option which allows the user to drive system level reset, interrupt and enable/disable lines directly without the need for an off-chip Open-Drain or Open-Collector buffer. Wire-OR logic functions can be performed at the printed circuit board level.

Pull-up Resistor

All pins have a programmable active pull-up. A typical resistor value for the pull-up ranges from 50kΩ to 80kΩ.

Output Latch (Bus Hold)

All pins have a programmable circuit that weakly holds the previously driven state when all drivers connected to the pin (including the pin's output driver as well as any other devices connected to the pin by external bus) are tristated.

Unique to the ispGDX160VA are user-programmable I/Os supporting either 3.3V or 2.5V output voltage level options. The ispGDX160VA uses a VCCIO pin to provide the 2.5V reference voltage when used. The ispGDX160VA VCCIO pin occupies the same location as VCC on the ispGDX160V, allowing drop-in replacement. The ispGDX160VA offers improved performance by reducing fanout delays and has PCI compatible drive capability.

Only the ispGDX160VA is available in the fastest (3.5ns) Commercial speed grade and in -5, -7, and -9ns Industrial grades in all packages.

The ispGDX160VA has a device ID different from the ispGDX160V requiring that the latest Lattice download software be used for programming and verification. Although the ispGDX160VA and ispGDX160V are functionally equivalent, they are not 100% JEDEC compatible. All design files must be recompiled targeting the ispGDX160VA.

The *ispGDXV/VA* Family architecture has been developed to deliver an in-system programmable signal routing solution with high speed and high flexibility. The devices are targeted for three similar but distinct classes of end-system applications:

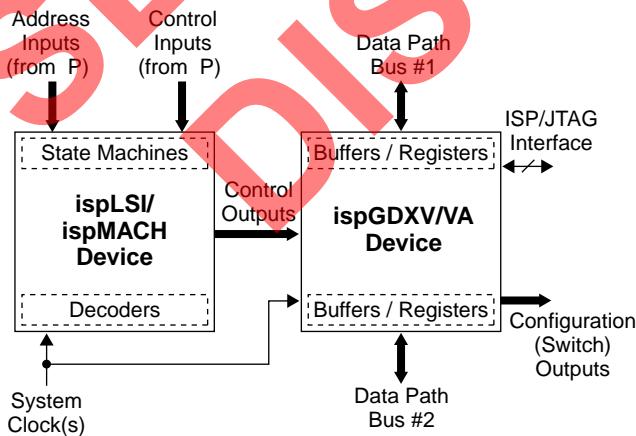
Programmable, Random Signal Interconnect (PRSI)

This class includes PCB-level programmable signal routing and may be used to provide arbitrary signal swapping between chips. It opens up the possibilities of programmable system hardware. It is characterized by the need to provide a large number of 1:1 pin connections which are statically configured, i.e., the pin-to-pin paths do not need to change dynamically in response to control inputs.

Programmable Data Path (PDP)

This application area includes system data path transceiver, MUX and latch functions. With today's 32- and 64-bit microprocessor buses, but standard data path glue components still relegated primarily to eight bits, PCBs are frequently crammed with a dozen or more data path glue chips that use valuable real estate. Many of these applications consist of "on-board" bus and memory interfaces that do not require the very high drive of standard glue functions but can benefit from higher integration. Therefore, there is a need for a flexible means to integrate these on-board data path functions in an analogous way to programmable logic's solution to control logic integration. Lattice's CPLDs make an ideal control logic complement to the *ispGDXV/VA* in-system programmable data path devices as shown below.

Figure 4. *ispGDXV/VA* Complements Lattice CPLDs



Programmable Switch Replacement (PSR)

Includes solid-state replacement and integration of mechanical DIP Switch and jumper functions. Through in-system programming, pins of the *ispGDXV/VA* devices can be driven to HIGH or LOW logic levels to emulate the traditional device outputs. PSR functions do not require any input pin connections.

These applications actually require somewhat different silicon features. PRSI functions require that the device support arbitrary signal routing on-chip between any two pins with no routing restrictions. The routing connections are static (determined at programming time) and each input-to-output path operates independently. As a result, there is little need for dynamic signal controls (OE, clocks, etc.). Because the *ispGDXV/VA* device will interface with control logic outputs from other components (such as *ispLSI* or *ispMACH™*) on the board (which frequently change late in the design process as control logic is finalized), there must be no restrictions on pin-to-pin signal routing for this type of application.

PDP functions, on the other hand, require the ability to dynamically switch signal routing (MUXing) as well as latch and tri-state output signals. As a result, the programmable interconnect is used to define *possible* signal routes that are then selected dynamically by control signals from an external MPU or control logic. These functions are usually formulated early in the conceptual design of a product. The data path requirements are driven by the microprocessor, bus and memory architecture defined for the system. This part of the design is the earliest portion of the system design frozen, and will not usually change late in the design because the result would be total system and PCB redesign. As a result, the ability to accommodate *arbitrary* any pin-to-any pin re-routing is not a strong requirement as long as the designer has the ability to define his functions with a reasonable degree of freedom initially.

As a result, the *ispGDXV/VA* architecture has been defined to support PSR and PRSI applications (including bidirectional paths) with no restrictions, while PDP applications (using dynamic MUXing) are supported with a minimal number of restrictions as described below. In this way, speed and cost can be optimized and the devices can still support the system designer's needs.

The following diagrams illustrate several *ispGDXV/VA* applications.

Figure 5. Address Demultiplex/Data Buffering

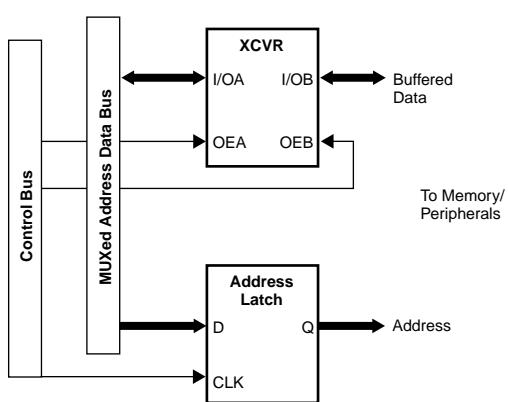


Figure 6. Data Bus Byte Swapper

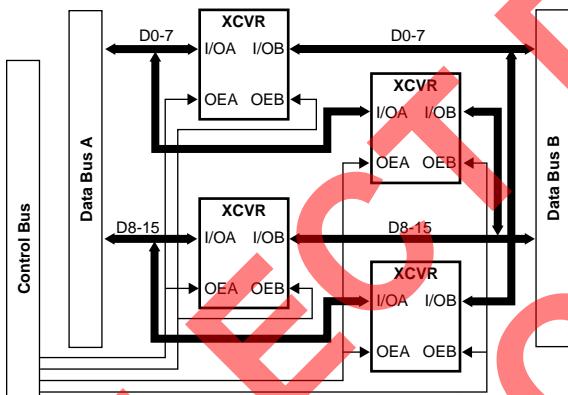
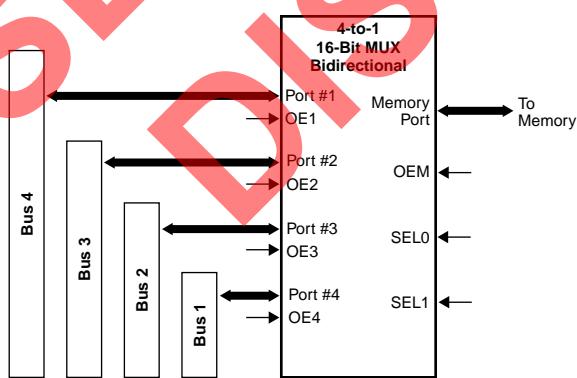


Figure 7. Four-Port Memory Interface



Note: All OE and SEL lines driven by external arbiter logic (not shown).

Designing with the *ispGDXV/VA*

As mentioned earlier, this architecture satisfies the PRSI class of applications without restrictions: any I/O pin as a single input or bidirectional can drive any other I/O pin as output.

For the case of PDP applications, the designer does have to take into consideration the limitations on pins that can be used as control (MUX0, MUX1, OE, CLK) or data (MUXA-D) inputs. The restrictions on control inputs are not likely to cause any major design issues because the input possibilities span 25% of the total pins.

The MUXA-D input partitioning requires that designers consciously assign pinouts so that MUX inputs are in the appropriate, disjoint groups. For example, since the MUXA group includes I/O0-39 (160 I/O device), it is not possible to use I/O0 and I/O9 in the same MUX function. As previously discussed, data path functions will be assigned early in the design process and these restrictions are reasonable in order to optimize speed and cost.

User Electronic Signature

The *ispGDXV/VA* Family includes dedicated User Electronic Signature (UES) E²CMOS storage to allow users to code design-specific information into the devices to identify particular manufacturing dates, code revisions, or the like. The UES information is accessible through the boundary scan programming port via a specific command. This information can be read even when the security cell is programmed.

Security

The *ispGDXV/VA* Family includes a security feature that prevents reading the device program once set. Even when set, it does not inhibit reading the UES or device ID code. It can be erased only via a device bulk erase.

Supply Voltage V_{CC} -0.5 to +5.4V
 Input Voltage Applied -0.5 to +5.6V
 Off-State Output Voltage Applied -0.5 to +5.6V
 Storage Temperature -65 to 150°C
 Case Temp. with Power Applied -55 to 125°C
 Max. Junction Temp. (T_J) with Power Applied ... 150°C

1. Stresses above those listed under the "Absolute Maximum Ratings" may cause permanent damage to the device. Functional operation of the device at these or at any other conditions above those indicated in the operational sections of this specification is not implied (while programming, follow the programming specifications).
2. Compliance with the Thermal Management section of the Lattice Semiconductor Data Book or CD-ROM is a requirement.

SYMBOL	PARAMETER		MIN.	MAX.	UNITS
V_{CC}	Supply Voltage	Commercial $T_A = 0^{\circ}\text{C}$ to $+70^{\circ}\text{C}$	3.00	3.60	V
		Industrial $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$	3.00	3.60	V
V_{CCIO}	I/O Reference Voltage		2.3	3.60	V

Table 2-0005/gdx160va

SYMBOL	PARAMETER	PACKAGE TYPE	TYPICAL	UNITS	TEST CONDITIONS
C_1	I/O Capacitance	PQFP	7	pf	$V_{CC} = 3.3\text{V}$, $V_{I/O} = 2.0\text{V}$
		BGA, fpBGA	10	pf	
C_2	Dedicated Clock Capacitance	PQFP	8	pf	$V_{CC} = 3.3\text{V}$, $V_Y = 2.0\text{V}$
		BGA, fpBGA	10	pf	

Table 2-0006/gdx160va

PARAMETER	MINIMUM	MAXIMUM	UNITS
Erase/Reprogram Cycles	10,000	—	Cycles

Input Pulse Levels	GND to VCCIO(MIN)
Input Rise and Fall Time	$\leq 1.5\text{ns}$ 10% to 90%
Input Timing Reference Levels	$V_{CCIO}(\text{MIN})/2$
Output Timing Reference Levels	$V_{CCIO}(\text{MIN})/2$
Output Load	See Figure 8

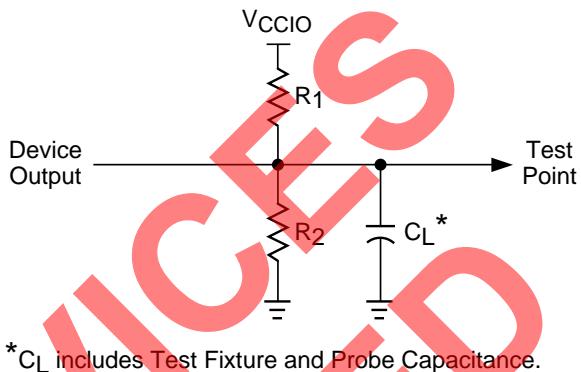
3-state levels are measured 0.5V from steady-state active level.

Output Load Conditions (See Figure 8)

TEST CONDITION	3.3V		2.5V		CL
	R1	R2	R1	R2	
A	153Ω	134Ω	156Ω	144Ω	35pF
B	Active High	∞	134Ω	∞	144Ω 35pF
	Active Low	153Ω	∞	156Ω	∞ 35pF
C	Active High to Z at $V_{OH}-0.5\text{V}$	∞	134Ω	∞	144Ω 5pF
	Active Low to Z at $V_{OL}+0.5\text{V}$	153Ω	∞	156Ω	∞ 5pF
D	Slow Slew	∞	∞	∞	∞ 35pF

Table 2-0004A/gdx160va

Figure 8. Test Load



* CL includes Test Fixture and Probe Capacitance.

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Over Recommended Operating Conditions

SYMBOL	PARAMETER	CONDITION	MIN.	TYP.	MAX.	UNITS
V_{CCIO}	I/O Reference Voltage	-	3.0	-	3.6	V
V_{IL}	Input Low Voltage	$V_{OH} \leq V_{OUT}$ or $V_{OUT} \leq V_{OL}(\text{MAX})$	-0.3	-	0.8	V
V_{IH}	Input High Voltage	$V_{OH} \leq V_{OUT}$ or $V_{OUT} \leq V_{OL}(\text{MAX})$	2.0	-	5.25	V
V_{OL}	Output Low Voltage	$V_{CC} = V_{CC}(\text{MIN})$	$I_{OL} = +100\mu\text{A}$	-	-	V
			$I_{OL} = +24\text{mA}$	-	-	V
V_{OH}	Output High Voltage	$V_{CC} = V_{CC}(\text{MIN})$	$I_{OH} = -100\mu\text{A}$	2.8	-	V
			$I_{OH} = -12\text{mA}$	2.4	-	V

1. I/O voltage configuration must be set to VCC.

Table 2-0007/gdx160va

Over Recommended Operating Conditions

SYMBOL	PARAMETER	CONDITION	MIN.	TYP.	MAX.	UNITS
V_{CCIO}	I/O Reference Voltage	—	2.3	—	2.7	V
V_{IL}	Input Low Voltage	$V_{OH(MIN)} \leq V_{OUT} \text{ or } V_{OUT} \leq V_{OL(MAX)}$	-0.3	—	0.7	V
V_{IH}	Input High Voltage	$V_{OH(MIN)} \leq V_{OUT} \text{ or } V_{OUT} \leq V_{OL(MAX)}$	1.7	—	5.25	V
V_{OL}	Output Low Voltage	$V_{CCIO=MIN}, I_{OL} = 100\mu A$	—	—	0.2	V
		$V_{CCIO=MIN}, I_{OL} = 8mA$	—	—	0.6	V
V_{OH}	Output High Voltage	$V_{CCIO=MIN}, I_{OH} = -100\mu A$	2.1	—	—	V
		$V_{CCIO=MIN}, I_{OH} = -8mA$	1.8	—	—	V

1. I/O voltage configuration must be set to VCCIO.

2.5Vgdx160va

Over Recommended Operating Conditions

SYMBOL	PARAMETER	CONDITION	MIN.	TYP. ²	MAX.	UNITS
I_{IL}	Input or I/O Low Leakage Current	$0V \leq V_{IN} \leq V_{IL(MAX)}$	—	—	-10	μA
I_{IH}	Input or I/O High Leakage Current	$(V_{CCIO}-0.2) \leq V_{IN} \leq V_{CCIO}$	—	—	10	μA
		$V_{CCIO} \leq V_{IN} \leq 5.25V$	—	—	50	μA
I_{PU}	I/O Active Pullup Current	$0V \leq V_{IN} \leq V_{IL(MAX)}$	—	—	-200	μA
I_{BHLS}	Bus Hold Low Sustaining Current	$V_{IN} = V_{IL(MAX)}$	40	—	—	μA
I_{BHHS}	Bus Hold High Sustaining Current	$V_{IN} = V_{IH(MIN)}$	-40	—	—	μA
I_{BHLO}	Bus Hold Low Overdrive Current	$0V \leq V_{IN} \leq V_{CCIO}$	—	—	550	μA
I_{BHHO}	Bus Hold High Overdrive Current	$0V \leq V_{IN} \leq V_{CCIO}$	—	—	-550	μA
I_{BHT}	Bus Hold Trip Points		V_{IL}	—	V_{IH}	V
I_{OS}¹	Output Short Circuit Current	$V_{CC} = 3.3V, V_{OUT} = 0.5V, T_A = 25^\circ C$	—	—	-250	mA
I_{CCQ}⁴	Quiescent Power Supply Current	$V_{IL} = 0.5V, V_{IH} = V_{CC}$	—	16.5	—	mA
I_{CC}	Dynamic Power Supply Current per Input Switching	One input toggling at 50% duty cycle, outputs open.	—	See Note 3	—	mA/MHz
I_{CONT}⁵	Maximum Continuous I/O Pin Sink Current Through Any GND Pin	—	—	—	160	mA

1. One output at a time for a maximum of one second. $V_{OUT} = 0.5V$ was selected to avoid test problems by tester ground degradation. Characterized, but not 100% tested.

DC Char_gdx160va

2. Typical values are at $V_{CC} = 3.3V$ and $T_A = 25^\circ C$.

3. $I_{CC} / \text{MHz} = (0.003 \times \text{I/O cell fanout}) + 0.029$.

e.g. An input driving four I/O cells at 40MHz results in a dynamic I_{CC} of approximately $((0.003 \times 4) + 0.029) \times 40 = 1.64\text{mA}$.

4. For a typical application with 50% of I/O pins used as inputs, 50% used as outputs or bi-directionals.

5. This parameter limits the total current sinking of I/O pins surrounding the nearest GND pin.

Over Recommended Operating Conditions

PARAMETER	TEST ¹ COND.	#	DESCRIPTION	-3		-5		UNITS
				MIN.	MAX.	MIN.	MAX.	
tpd²	A	1	Data Prop. Delay from Any I/O pin to Any I/O Pin (4:1 MUX)	—	3.5	—	5.0	ns
t_{sel}²	A	2	Data Prop. Delay from MUXsel Inputs to Any Output (4:1 MUX)	—	3.5	—	5.0	ns
f_{max} (Tog.)	—	3	Clock Frequency, Max. Toggle	250	—	143	—	MHz
f_{max} (Ext.)	—	4	Clock Frequency with External Feedback ($\frac{1}{tsu3+tgco1}$)	166.7	—	111	—	MHz
tsu1	—	5	Input Latch or Register Setup Time Before Y _x	3.0	—	4.0	—	ns
tsu2	—	6	Input Latch or Register Setup Time Before I/O Clock	2.5	—	3.0	—	ns
tsu3	—	7	Output Latch or Register Setup Time Before Y _x	2.5	—	4.0	—	ns
tsu4	—	8	Output Latch or Register Setup Time Before I/O Clock	2.0	—	3.0	—	ns
tsuce1	—	9	Global Clock Enable Setup Time Before Y _x	2.5	—	2.5	—	ns
tsuce2	—	10	Global Clock Enable Setup Time Before I/O Clock	1.5	—	1.5	—	ns
tsuce3	—	11	I/O Clock Enable Setup Time Before Y _x	3.0	—	4.5	—	ns
th1	—	12	Input Latch or Reg. Hold Time (Y _x)	0.0	—	0.0	—	ns
th2	—	13	Input Latch or Reg. Hold Time (I/O Clock)	0.5	—	1.5	—	ns
th3	—	14	Output Latch or Reg. Hold Time (Y _x)	0.0	—	0.0	—	ns
th4	—	15	Output Latch or Reg. Hold Time (I/O Clock)	1.0	—	1.5	—	ns
thce1	—	16	Global Clock Enable Hold Time (Y _x)	0.0	—	0.0	—	ns
thce2	—	17	Global Clock Enable Hold Time (I/O Clock)	1.0	—	1.5	—	ns
thce3	—	18	I/O Clock Enable Hold Time (Y _x)	0.0	—	0.0	—	ns
tgco1²	A	19	Output Latch or Reg. Clock (from Y _x) to Output Delay	—	3.5	—	5.0	ns
tgco2²	A	20	Input Latch or Register Clock (from Y _x) to Output Delay	—	6.0	—	8.5	ns
tco1²	A	21	Output Latch or Register Clock (from I/O pin) to Output Delay	—	4.0	—	6.0	ns
tco2²	A	22	Input Latch or Register Clock (from I/O pin) to Output Delay	—	7.0	—	9.5	ns
ten²	B	23	Input to Output Enable	—	5.0	—	6.0	ns
tdis²	C	24	Input to Output Disable	—	5.0	—	6.0	ns
ttoeen²	B	25	Test OE Output Enable	—	6.0	—	6.0	ns
ttoedis²	C	26	Test OE Output Disable	—	6.0	—	6.0	ns
twh	—	27	Clock Pulse Duration, High	2.0	—	3.5	—	ns
twl	—	28	Clock Pulse Duration, Low	2.0	—	3.5	—	ns
trst	—	29	Register Reset Delay from RESET Low	—	8.0	—	14.0	ns
trw	—	30	Reset Pulse Width	5.0	—	10.0	—	ns
tsl	D	31	Output Delay Adder for Output Timings Using Slow Slew Rate	—	3.5	—	5.0	ns
tsk	A	32	Output Skew (tgco1 Across Chip)	—	0.5	—	0.5	ns

1. All timings measured with one output switching, fast output slew rate setting, except tsl.
 2. The delay parameters are measured with Vcc as I/O voltage reference. An additional 0.5ns delay is incurred when Vccio is used as I/O voltage reference.

Over Recommended Operating Conditions

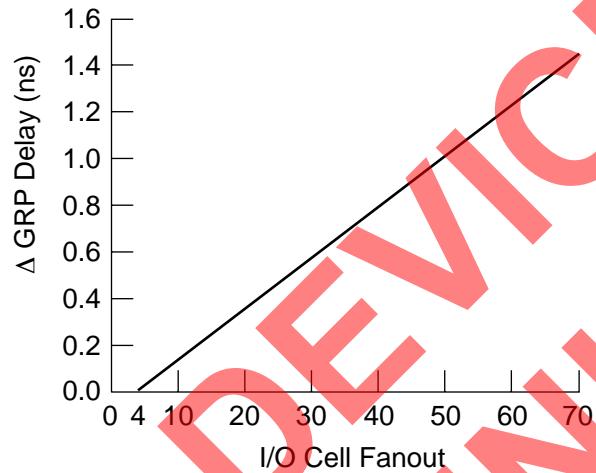
PARAMETER	TEST ¹ COND.	#	DESCRIPTION	-7		-9		UNITS
				MIN.	MAX.	MIN.	MAX.	
t_{pd}²	A	1	Data Prop. Delay from Any I/O pin to Any I/O Pin (4:1 MUX)	—	7.0	—	9.0	ns
t_{sel}²	A	2	Data Prop. Delay from MUXsel Inputs to Any Output (4:1 MUX)	—	7.0	—	9.0	ns
f_{max} (Tog.)	—	3	Clock Frequency, Max. Toggle	100	—	83	—	MHz
f_{max} (Ext.)	—	4	Clock Frequency with External Feedback ($\frac{1}{tsu3+tgco1}$)	80	—	62.5	—	MHz
tsu1	—	5	Input Latch or Register Setup Time Before Y _x	5.5	—	7.0	—	ns
tsu2	—	6	Input Latch or Register Setup Time Before I/O Clock	4.5	—	6.0	—	ns
tsu3	—	7	Output Latch or Register Setup Time Before Y _x	5.5	—	7.0	—	ns
tsu4	—	8	Output Latch or Register Setup Time Before I/O Clock	4.5	—	6.0	—	ns
tsuce1	—	9	Global Clock Enable Setup Time Before Y _x	3.5	—	4.0	—	ns
tsuce2	—	10	Global Clock Enable Setup Time Before I/O Clock	2.5	—	3.0	—	ns
tsuce3	—	11	I/O Clock Enable Setup Time Before Y _x	6.5	—	8.5	—	ns
th1	—	12	Input Latch or Reg. Hold Time (Y _x)	0.0	—	0.0	—	ns
th2	—	13	Input Latch or Reg. Hold Time (I/O Clock)	2.5	—	3.0	—	ns
th3	—	14	Output Latch or Reg. Hold Time (Y _x)	0.0	—	0.0	—	ns
th4	—	15	Output Latch or Reg. Hold Time (I/O Clock)	2.5	—	3.0	—	ns
thce1	—	16	Global Clock Enable Hold Time (Y _x)	0.0	—	0.0	—	ns
thce2	—	17	Global Clock Enable Hold Time (I/O Clock)	2.5	—	3.0	—	ns
thce3	—	18	I/O Clock Enable Hold Time (Y _x)	0.0	—	0.0	—	ns
tgco1²	A	19	Output Latch or Reg. Clock (from Y _x) to Output Delay	—	7.0	—	9.0	ns
tgco2²	A	20	Input Latch or Register Clock (from Y _x) to Output Delay	—	11.0	—	13.5	ns
tco1²	A	21	Output Latch or Register Clock (from I/O pin) to Output Delay	—	9.0	—	11.5	ns
tco2²	A	22	Input Latch or Register Clock (from I/O pin) to Output Delay	—	13.0	—	15.7	ns
ten²	B	23	Input to Output Enable	—	8.5	—	10.5	ns
tdis²	C	24	Input to Output Disable	—	8.5	—	10.5	ns
ttoeen²	B	25	Test OE Output Enable	—	8.5	—	10.5	ns
ttoedis²	C	26	Test OE Output Disable	—	8.5	—	10.5	ns
twh	—	27	Clock Pulse Duration, High	5.0	—	6.0	—	ns
twl	—	28	Clock Pulse Duration, Low	5.0	—	6.0	—	ns
trst	—	29	Register Reset Delay from RESET Low	—	18.0	—	22.0	ns
trw	—	30	Reset Pulse Width	14.0	—	18.0	—	ns
tsl	D	31	Output Delay Adder for Output Timings Using Slow Slew Rate	—	7.0	—	9.0	ns
tsk	A	32	Output Skew (tgco1 Across Chip)	—	0.5	—	1.0	ns

1. All timings measured with one output switching, fast output slew rate setting, except tsl.
 2. The delay parameters are measured with Vcc as I/O voltage reference. An additional 0.5ns delay is incurred when Vccio is used as I/O voltage reference.

ispGDX160VA timings are specified with a GRP load (fanout) of four I/O cells. The figure below shows the Δ GRP Delay with increased GRP loads. These deltas

apply to any signal path traversing the GRP (MUXA-D, OE, CLK/CLKEN, MUXsel0-1). Global Clock signals which do not use the GRP have no fanout delay adder.

ispGDX160VA Maximum Δ GRP Delay vs. I/O Cell Fanout



**SELECT
DISCONTINUED**

Over Recommended Operating Conditions

PARAMETER	#	DESCRIPTION ¹	-3		-5		UNITS
			MIN.	MAX.	MIN.	MAX.	
Inputs							
t _{io}	32	Input Buffer Delay	—	0.4	—	0.9	ns
GRP							
t _{grp}	33	GRP Delay	—	1.1	—	1.1	ns
MUX							
t _{muxd}	34	I/O Cell MUX A/B/C/D Data Delay	—	1.0	—	1.5	ns
t _{muxexp}	35	I/O Cell MUX A/B/C/D Expander Delay	—	1.5	—	2.0	ns
t _{muxs}	36	I/O Cell Data Select	—	1.0	—	1.5	ns
t _{muxsio}	37	I/O Cell Data Select (I/O Clock)	—	1.5	—	3.0	ns
t _{muxsg}	38	I/O Cell Data Select (Yx Clock)	—	1.5	—	2.0	ns
t _{muxselexp}	39	I/O Cell MUX Data Select Expander Delay	—	1.5	—	2.0	ns
Register							
t _{iolat}	40	I/O Latch Delay	—	1.0	—	1.0	ns
t _{iosu}	41	I/O Register Setup Time Before Clock	—	0.8	—	2.0	ns
t _{ioh}	42	I/O Register Hold Time After Clock	—	1.7	—	1.5	ns
t _{ioco}	43	I/O Register Clock to Output Delay	—	1.2	—	0.5	ns
t _{ior}	44	I/O Reset to Output Delay	—	1.0	—	1.5	ns
t _{cesu}	45	I/O Clock Enable Setup Time Before Clock	—	2.3	—	2.0	ns
t _{cех}	46	I/O Clock Enable Hold Time After Clock	—	0.2	—	0.5	ns
Data Path							
t _{fdbk}	47	I/O Register Feedback Delay	—	0.6	—	0.9	ns
t _{iobp}	48	I/O Register Bypass Delay	—	0.0	—	0.0	ns
t _{ioob}	49	I/O Register Output Buffer Delay	—	0.0	—	0.0	ns
t _{muxcg}	50	I/O Register A/B/C/D Data Input MUX Delay (Yx Clock)	—	1.5	—	2.0	ns
t _{muxcio}	51	I/O Register A/B/C/D Data Input MUX Delay (I/O Clock)	—	1.5	—	3.0	ns
t _{iodg}	52	I/O Register I/O MUX Delay (Yx Clock)	—	3.5	—	4.0	ns
t _{iodio}	53	I/O Register I/O MUX Delay (I/O Clock)	—	3.5	—	5.0	ns
Outputs							
t _{ob}	54	Output Buffer Delay	—	1.0	—	1.5	ns
t _{obs}	55	Output Buffer Delay (Slow Slew Option)	—	4.5	—	6.5	ns
t _{toeen}	56	I/O Cell OE to Output Enable	—	3.5	—	4.0	ns
t _{toedis}	57	I/O Cell OE to Output Disable	—	3.5	—	4.0	ns
t _{goe}	58	GRP Output Enable and Disable Delay	—	0.0	—	0.0	ns
t _{oe}	59	Test OE Enable and Disable Delay	—	2.5	—	2.0	ns
Clocks							
t _{ioclk}	60	I/O Clock Delay	—	0.3	—	2.0	ns
t _{gclk}	61	Global Clock Delay	—	1.3	—	2.0	ns
t _{gclkeng}	62	Global Clock Enable (Yx Clock)	—	1.5	—	2.5	ns
t _{gclkenio}	63	Global Clock Enable (I/O Clock)	—	1.0	—	3.5	ns
t _{ioclkeng}	64	I/O Clock Enable (Yx Clock)	—	0.5	—	2.5	ns
Global Reset							
t _{gr}	65	Global Reset to I/O Register Latch	—	6.0	—	11.0	ns

1. Internal Timing Parameters are not tested and are for reference only.

2. Refer to the Timing Model in this data sheet for further details.

Over Recommended Operating Conditions

PARAMETER	#	DESCRIPTION ¹	-7		-9		UNITS
			MIN.	MAX.	MIN.	MAX.	
Inputs							
t _{io}	32	Input Buffer Delay	—	1.4	—	1.9	ns
GRP							
t _{grp}	33	GRP Delay	—	1.1	—	1.1	ns
MUX							
t _{muxd}	34	I/O Cell MUX A/B/C/D Data Delay	—	2.0	—	2.5	ns
t _{muxexp}	35	I/O Cell MUX A/B/C/D Expander Delay	—	2.5	—	3.0	ns
t _{muxs}	36	I/O Cell Data Select	—	2.0	—	2.5	ns
t _{muxsio}	37	I/O Cell Data Select (I/O Clock)	—	4.5	—	6.0	ns
t _{muxsg}	38	I/O Cell Data Select (Yx Clock)	—	2.5	—	3.0	ns
t _{muxselexp}	39	I/O Cell MUX Data Select Expander Delay	—	2.5	—	3.0	ns
Register							
t _{iolat}	40	I/O Latch Delay	—	1.0	—	1.0	ns
t _{iosu}	41	I/O Register Setup Time Before Clock	—	3.2	—	4.4	ns
t _{ioh}	42	I/O Register Hold Time After Clock	—	2.3	—	2.6	ns
t _{ioco}	43	I/O Register Clock to Output Delay	—	0.5	—	0.5	ns
t _{ior}	44	I/O Reset to Output Delay	—	1.5	—	1.5	ns
t _{cesu}	45	I/O Clock Enable Setup Time Before Clock	—	2.5	—	2.0	ns
t _{cех}	46	I/O Clock Enable Hold Time After Clock	—	1.0	—	2.0	ns
Data Path							
t _{fdbk}	47	I/O Register Feedback Delay	—	1.2	—	1.3	ns
t _{iobp}	48	I/O Register Bypass Delay	—	0.3	—	0.6	ns
t _{ioob}	49	I/O Register Output Buffer Delay	—	0.6	—	0.7	ns
t _{muxcg}	50	I/O Register A/B/C/D Data Input MUX Delay (Yx Clock)	—	2.5	—	3.0	ns
t _{muxcio}	51	I/O Register A/B/C/D Data Input MUX Delay (I/O Clock)	—	4.5	—	6.0	ns
t _{iodg}	52	I/O Register I/O MUX Delay (Yx Clock)	—	5.0	—	6.0	ns
t _{iodio}	53	I/O Register I/O MUX Delay (I/O Clock)	—	7.0	—	9.0	ns
Outputs							
t _{ob}	54	Output Buffer Delay	—	2.2	—	2.9	ns
t _{obs}	55	Output Buffer Delay (Slow Slew Option)	—	9.2	—	11.9	ns
t _{toeen}	56	I/O Cell OE to Output Enable	—	6.0	—	7.5	ns
t _{toedis}	57	I/O Cell OE to Output Disable	—	6.0	—	7.5	ns
t _{goe}	58	GRP Output Enable and Disable Delay	—	0.0	—	0.0	ns
t _{oe}	59	Test OE Enable and Disable Delay	—	2.5	—	3.0	ns
Clocks							
t _{ioclk}	60	I/O Clock Delay	—	3.2	—	4.4	ns
t _{gclk}	61	Global Clock Delay	—	2.7	—	3.4	ns
t _{gclkeng}	62	Global Clock Enable (Yx Clock)	—	3.7	—	5.4	ns
t _{gclkenio}	63	Global Clock Enable (I/O Clock)	—	5.7	—	8.4	ns
t _{ioclkeng}	64	I/O Clock Enable (Yx Clock)	—	4.2	—	6.4	ns
Global Reset							
t _{gr}	65	Global Reset to I/O Register Latch	—	13.7	—	16.4	ns

1. Internal Timing Parameters are not tested and are for reference only.

2. Refer to the Timing Model in this data sheet for further details.

Supply Voltage V_{CC} -0.5 to +5.4V
 Input Voltage Applied -0.5 to +5.6V
 Off-State Output Voltage Applied -0.5 to +5.6V
 Storage Temperature -65 to 150°C
 Case Temp. with Power Applied -55 to 125°C
 Max. Junction Temp. (T_J) with Power Applied ... 150°C

1. Stresses above those listed under the "Absolute Maximum Ratings" may cause permanent damage to the device. Functional operation of the device at these or at any other conditions above those indicated in the operational sections of this specification is not implied (while programming, follow the programming specifications).
2. Compliance with the Thermal Management section of the Lattice Semiconductor Data Book or CD-ROM is a requirement.

SYMBOL	PARAMETER		MIN.	MAX.	UNITS
V_{CC}	Supply Voltage	Commercial $T_A = 0^{\circ}\text{C}$ to $+70^{\circ}\text{C}$	3.0	3.6	V
		Industrial $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$	3.0	3.6	V
V_{IL}^1	Input Low Voltage		-0.3	0.8	V
V_{IH}^1	Input High Voltage		2.0	5.25	V

1. Typical 100mV of input hysteresis.

Table 2-0005/gdxv

SYMBOL	PARAMETER	TYPICAL	UNITS	TEST CONDITIONS
C_1	I/O Capacitance	8	pf	$V_{CC} = 3.3\text{V}$, $V_{I/O} = 2.0\text{V}$
C_2	Dedicated Clock Capacitance	10	pf	$V_{CC} = 3.3\text{V}$, $V_Y = 2.0\text{V}$

Table 2 - 0006

PARAMETER	MINIMUM	MAXIMUM	UNITS
Erase/Reprogram Cycles	10,000	—	Cycles

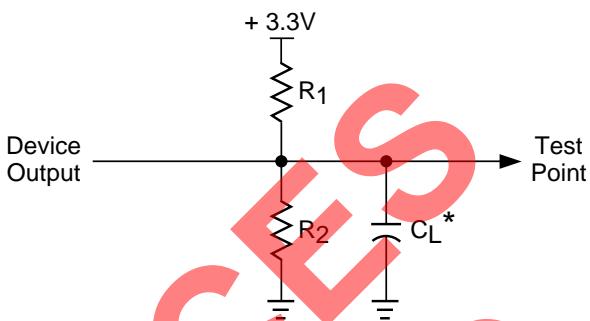
Input Pulse Levels	GND to 3.0V
Input Rise and Fall Time	$\leq 1.5\text{ns}$ 10% to 90%
Input Timing Reference Levels	1.5V
Output Timing Reference Levels	1.5V
Output Load	See figure at right

3-state levels are measured 0.5V from steady-state active level.

Output Load Conditions

TEST CONDITION	R1	R2	CL	
A	153Ω	134Ω	35pF	
B	Active High	∞ □	134Ω	35pF
	Active Low	153Ω	∞ □	35pF
C	Active High to Z at $V_{OH}-0.5\text{V}$	∞ □	134Ω	5pF
	Active Low to Z at $V_{OL}+0.5\text{V}$	153Ω	∞ □	5pF
D	Slow Slew	∞ □	∞ □	35pF

Table 2-0004A



* C_L includes Test Fixture and Probe Capacitance.

Over Recommended Operating Conditions

SYMBOL	PARAMETER	CONDITION	MIN.	TYP. ²	MAX.	UNITS
V_{OL}	Output Low Voltage	$I_{OL} = 24\text{ mA}$	—	—	0.55	V
V_{OH}	Output High Voltage	$I_{OH} = -12\text{ mA}$	2.4	—	—	V
I_{IL}	Input or I/O Low Leakage Current	$0\text{V} \leq V_{IN} \leq V_{IL}$ (Max.)	—	—	-10	μA
I_{IH}	Input or I/O High Leakage Current	$V_{CC} \leq V_{IN} \leq 5.25\text{V}$	—	—	10	μA
I_{IL-PU}	I/O Active Pull-Up Current	$0\text{V} \leq V_{IN} \leq V_{IL}$	—	—	-150	μA
I_{BHLS}	Bus Hold Low Sustaining Current	$V_{IN} = V_{IL}$ (Max.)	50	—	—	μA
I_{BHHS}	Bus Hold High Sustaining Current	$V_{IN} = V_{IH}$ (Min.)	-50	—	—	μA
I_{BHLO}	Bus Hold Low Overdrive Current	$0\text{V} \leq V_{IN} \leq V_{CC}$	—	—	550	μA
I_{BHHO}	Bus Hold High Overdrive Current	$0\text{V} \leq V_{IN} \leq V_{CC}$	—	—	-550	μA
I_{BHT}	Bus Hold Trip Points		V_{IL}	—	V_{IH}	V
I_{OS1}	Output Short Circuit Current	$V_{CC} = 3.3\text{V}$, $V_{OUT} = 0.5\text{V}$, $T_A = 25^\circ\text{C}$	—	—	-250	mA
I_{CCQ4}	Quiescent Power Supply Current	$V_{IL} = 0.5\text{V}$, $V_{IH} = V_{CC}$	—	70	—	mA
I_{CC}	Dynamic Power Supply Current per Input Switching	One input toggling @ 50% duty cycle, outputs open.	—	See Note 3	—	mA/MHz
I_{CONT5}	Maximum Continuous I/O Pin Sink Current Through Any GND Pin		—	—	96	mA

- One output at a time for a maximum duration of one second. $V_{OUT} = 0.5\text{V}$ was selected to avoid test problems by tester ground degradation. Characterized but not 100% tested.
- Typical values are at $V_{CC} = 3.3\text{V}$ and $T_A = 25^\circ\text{C}$.
- $I_{CC} / \text{MHz} = (0.01 \times \text{I/O cell fanout}) + 0.04$
e.g. An input driving four I/O cells at 40 MHz results in a dynamic I_{CC} of approximately $((0.01 \times 4) + 0.04) \times 40 = 3.2\text{ mA}$.
- For a typical application with 50% of I/O pins used as inputs, 50% used as outputs or bidirectionals.
- This parameter limits the total current sinking of I/O pins surrounding the nearest GND pin.

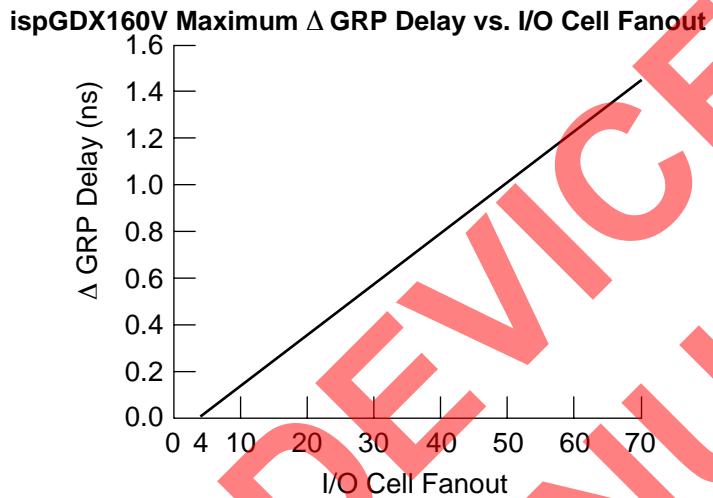
Over Recommended Operating Conditions

PARAMETER	TEST COND.	#	DESCRIPTION	-5		-7		UNITS
				MIN.	MAX.	MIN.	MAX.	
tpd	A	1	Data Prop. Delay from Any I/O pin to Any I/O pin (4:1 MUX)	—	5.0	—	7.0	ns
tsel	A	2	Data Prop. Delay from MUXsel Inputs to Any Output (4:1 MUX)	—	6.5	—	9.0	ns
fmax (Tog.)	—	3	Clock Frequency, Max. Toggle	143	—	100	—	MHz
fmax (Ext.)	—	4	Clock Frequency with External Feedback ($\frac{1}{tsu3+tgco1}$)	110	—	80.0	—	MHz
tsu1	—	5	Input Latch or Register Setup Time Before Y_x	4.0	—	5.5	—	ns
tsu2	—	6	Input Latch or Register Setup Time Before I/O Clock	3.0	—	4.5	—	ns
tsu3	—	7	Output Latch or Register Setup Time Before Y_x	4.0	—	5.5	—	ns
tsu4	—	8	Output Latch or Register Setup Time Before I/O Clock	3.0	—	4.5	—	ns
tsuce1	—	9	Global Clock Enable Setup Time Before Y_x	2.5	—	3.5	—	ns
tsuce2	—	10	Global Clock Enable Setup Time Before I/O Clock	1.5	—	2.5	—	ns
tsuce3	—	11	I/O Clock Enable Setup Time Before Y_x	4.5	—	6.5	—	ns
th1	—	12	Input Latch or Register Hold Time (Y_x)	0.0	—	0.0	—	ns
th2	—	13	Input Latch or Register Hold Time (I/O Clock)	1.5	—	2.5	—	ns
th3	—	14	Output Latch or Register Hold Time (Y_x)	0.0	—	0.0	—	ns
th4	—	15	Output Latch or Register Hold Time (I/O Clock)	1.5	—	2.5	—	ns
thce1	—	16	Global Clock Enable Hold Time (Y_x)	0.0	—	0.0	—	ns
thce2	—	17	Global Clock Enable Hold Time (I/O Clock)	1.5	—	2.5	—	ns
thce3	—	18	I/O Clock Enable Hold Time (Y_x)	0.0	—	0.0	—	ns
tgco1	A	19	Output Latch or Register Clock (from Y_x) to Output Delay	—	5.0	—	7.0	ns
tgco2	A	20	Input Latch or Register Clock (from Y_x) to Output Delay	—	8.5	—	11.0	ns
tco1	A	21	Output Latch or Register Clock (from I/O pin) to Output Delay	—	6.0	—	9.0	ns
tco2	A	22	Input Latch or Register Clock (from I/O pin) to Output Delay	—	9.5	—	13.0	ns
ten	B	23	Input to Output Enable	—	6.0	—	8.5	ns
tdis	C	24	Input to Output Disable	—	6.0	—	8.5	ns
ttoeen	B	25	Test OE Output Enable	—	9.0	—	12.0	ns
ttoedis	C	26	Test OE Output Disable	—	9.0	—	12.0	ns
twh	—	27	Clock Pulse Duration, High	3.5	—	5.0	—	ns
twl	—	28	Clock Pulse Duration, Low	3.5	—	5.0	—	ns
trst	—	29	Register Reset Delay from RESET Low	—	14.0	—	18.0	ns
trw	—	30	Reset Pulse Width	10.0	—	14.0	—	ns
tsl	D	31	Output Delay Adder for Output Timings Using Slow Slew Rate	—	8.0	—	12.0	ns
tsk	A	32	Output Skew (tgco1 Across Chip)	—	0.5	—	0.5	ns

1. All timings measured with one output switching, fast output slew rate setting, except tsl.

ispGDX160V timings are specified with a GRP load (fanout) of four I/O cells. The figure below shows the Δ GRP Delay with increased GRP loads. These deltas

apply to any signal path traversing the GRP (MUXA-D, OE, CLK/CLKEN, MUXsel0-1). Global Clock signals which do not use the GRP have no fanout delay adder.



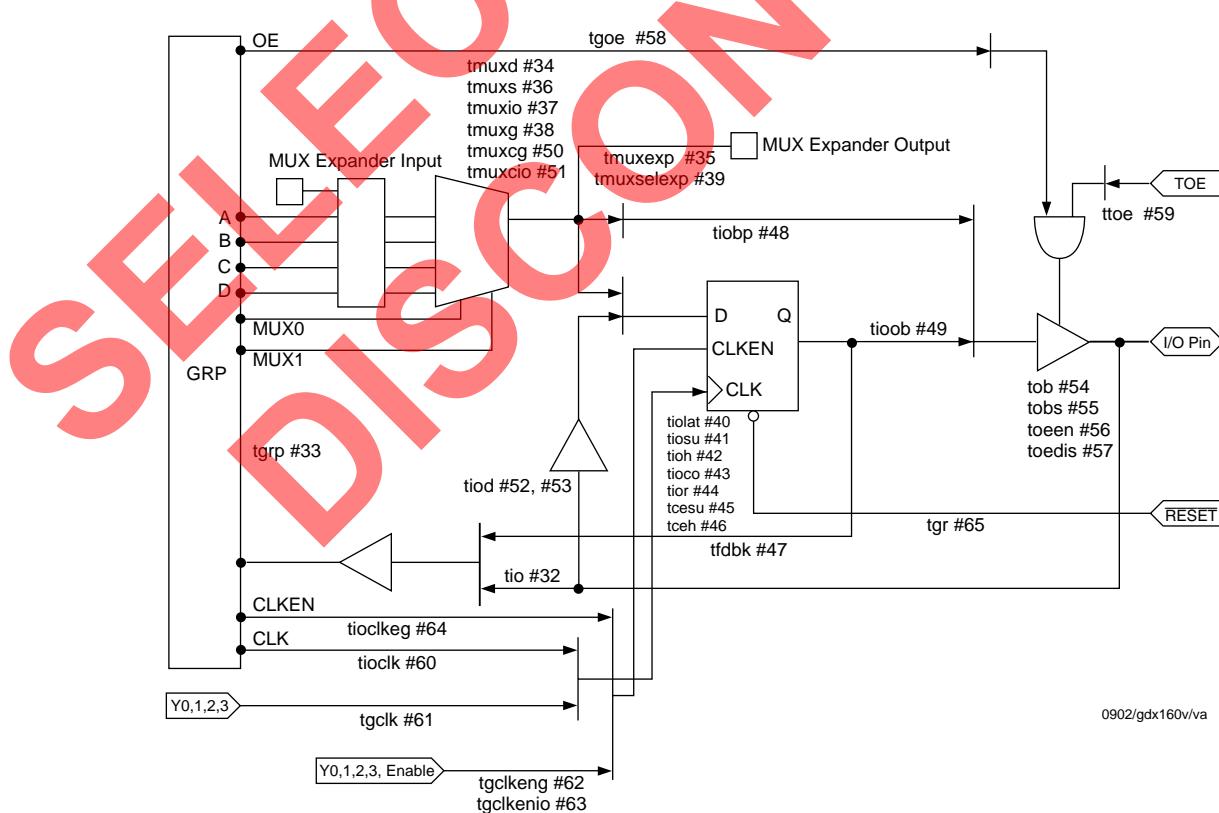
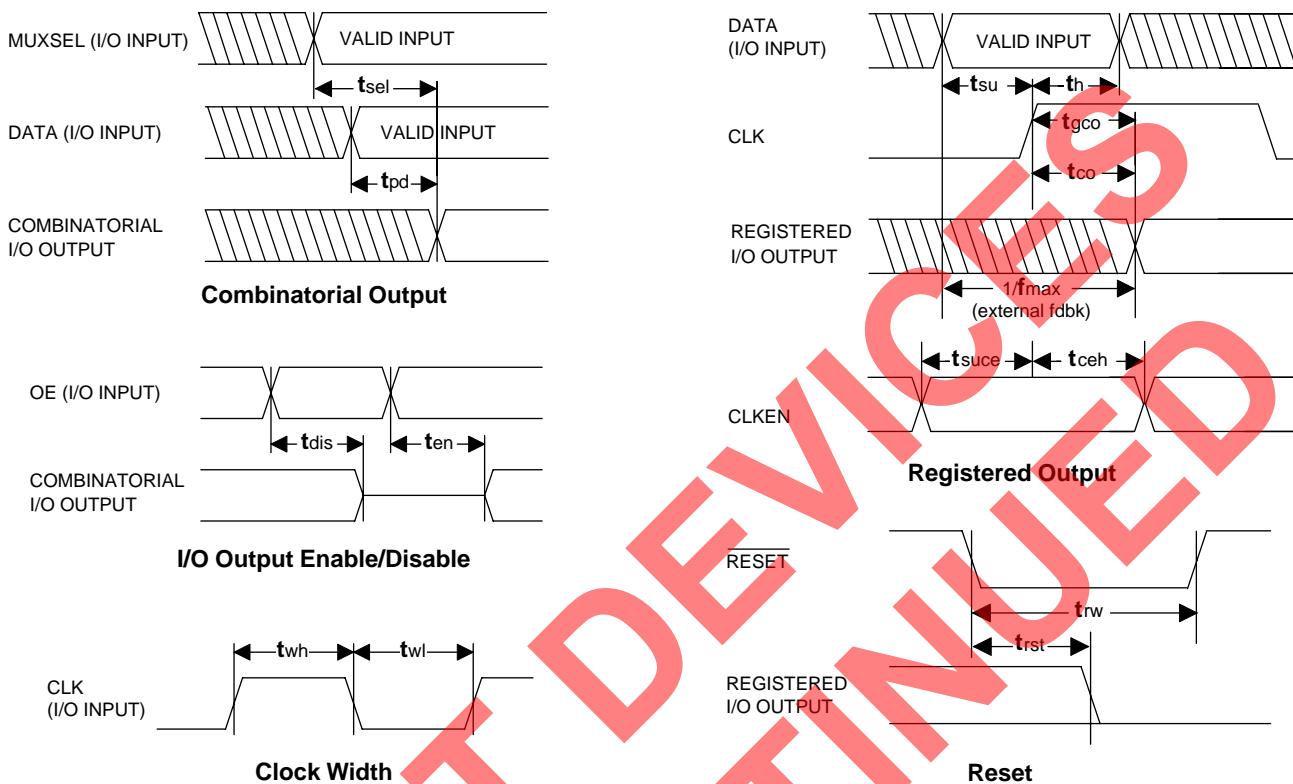
SELECT DEVICES DISCONTINUED

Over Recommended Operating Conditions

PARAMETER	#	DESCRIPTION ¹	-5		-7		UNITS
			MIN.	MAX.	MIN.	MAX.	
Inputs							
t _{io}	32	Input Buffer Delay	—	0.9	—	1.4	ns
GRP							
t _{grp}	33	GRP Delay	—	1.1	—	1.1	ns
MUX							
t _{muxd}	34	I/O Cell MUX A/B/C/D Data Delay	—	1.5	—	2.0	ns
t _{muxexp}	35	I/O Cell MUX A/B/C/D Expander Delay	—	2.0	—	2.5	ns
t _{muxs}	36	I/O Cell Data Select	—	3.0	—	4.0	ns
t _{muxsio}	37	I/O Cell Data Select (I/O Clk)	—	4.5	—	6.5	ns
t _{muxsg}	38	I/O Cell Data Select (Yx Clk)	—	3.5	—	4.5	ns
t _{muxselexp}	39	I/O Cell MUX Data Select Expander Delay	—	3.5	—	4.5	ns
Register							
t _{iolat}	40	I/O Latch Delay	—	1.0	—	1.0	ns
t _{iosu}	41	I/O Register Setup Time Before Clock	—	2.0	—	3.2	ns
t _{ioh}	42	I/O Register Hold Time After Clock	—	1.5	—	2.3	ns
t _{ioco}	43	I/O Register Clock to Output Delay	—	0.5	—	0.5	ns
t _{ior}	44	I/O Reset to Output Delay	—	1.5	—	1.5	ns
t _{cesu}	45	I/O Clock Enable Setup Time Before Clock	—	2.0	—	2.5	ns
t _{ceh}	46	I/O Clock Enable Hold Time After Clock	—	0.5	—	1.0	ns
Data Path							
t _{fdbk}	47	I/O Register Feedback Delay	—	0.9	—	1.2	ns
t _{iobp}	48	I/O Register Bypass Delay	—	0.0	—	0.3	ns
t _{ioob}	49	I/O Register Output Buffer Delay	—	0.0	—	0.6	ns
t _{muxcg}	50	I/O Register A/B/C/D Data Input MUX Delay (Yx Clk)	—	2.0	—	2.5	ns
t _{muicio}	51	I/O Register A/B/C/D Data Input MUX Delay (I/O Clk)	—	3.0	—	4.5	ns
t _{iodg}	52	I/O Register I/O MUX Delay (Yx Clk)	—	4.0	—	5.0	ns
t _{iodio}	53	I/O Register I/O MUX Delay (I/O Clk)	—	5.0	—	7.0	ns
Outputs							
t _{ob}	54	Output Buffer Delay	—	1.5	—	2.2	ns
t _{obs}	55	Output Buffer Delay (Slow Slew Option)	—	9.5	—	14.2	ns
t _{toen}	56	I/O Cell OE to Output Enable	—	4.0	—	6.0	ns
t _{toedis}	57	I/O Cell OE to Output Disable	—	4.0	—	6.0	ns
t _{goe}	58	GRP Output Enable and Disable Delay	—	0.0	—	0.0	ns
t _{oe}	59	Test OE Enable and Disable Delay	—	5.0	—	6.0	ns
Clocks							
t _{ioclk}	60	I/O Clock Delay	—	2.0	—	3.2	ns
t _{gclk}	61	Global Clock Delay	—	2.0	—	2.7	ns
t _{gclkeng}	62	Global Clock Enable (Yx Clk)	—	2.5	—	3.7	ns
t _{gclkenio}	63	Global Clock Enable (I/O Clk)	—	3.5	—	5.7	ns
t _{iockeng}	64	I/O Clock Enable (Yx Clk)	—	2.5	—	4.2	ns
Global Reset							
t _{gr}	65	Global Reset to I/O Register Latch	—	11.0	—	13.7	ns

1. Internal Timing Parameters are not tested and are for reference only.

2. Refer to the Timing Model in this data sheet for further details.



0902/gdx160v/va

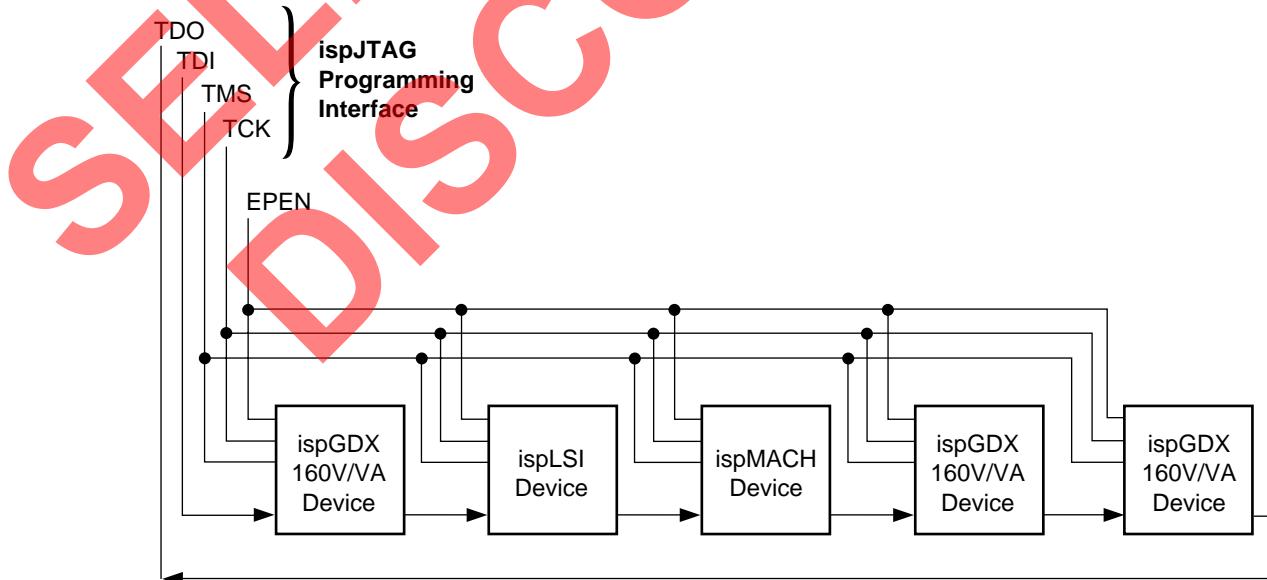
The ispLEVER Development System supports ispGDX design using a VHDL or Verilog language syntax. From creation to in-system programming, the ispLEVER system is an easy-to-use, self-contained design tool.

Features

- VHDL and Verilog Synthesis Support Available
- ispGDX Design Compiler
 - Design Rule Checker
 - I/O Connectivity Checker
 - Automatic Compiler Function
- Industry Standard JEDEC File for Programming
- Min/Max Timing Report
- Interfaces To Popular Timing Simulators
- User Electronic Signature (UES) Support
- Detailed Log and Report Files For Easy Design Debug
- On-line Help
- Windows® XP, Windows 2000, Windows 98 and Windows NT® Compatible
- Solaris® and HP-UX Versions Available

All necessary programming of the ispGDXV/VA is done via four TTL level logic interface signals. These four

Figure 9. ispJTAG Device Programming Interface



signals are fed into the on-chip programming circuitry where a state machine controls the programming.

On-chip programming can be accomplished using an IEEE 1149.1 boundary scan protocol. The IEEE 1149.1-compliant interface signals are Test Data In (TDI), Test Data Out (TDO), Test Clock (TCK) and Test Mode Select (TMS) control. The EPEN pin is also used to enable or disable the JTAG port.

The embedded controller port enable pin (EPEN) is used to enable the JTAG tap controller and in that regard has similar functionality to a TRST pin. When the pin is driven high, the JTAG TAP controller is enabled. This is also true when the pin is left unconnected, in which case the pin is pulled high by the permanent internal pullup. This allows ISP programming and BSCAN testing to take place as specified by the Instruction Table.

When the pin is driven low, the JTAG TAP controller is driven to a reset state asynchronously. It stays there while the pin is held low. After pulling the pin high the JTAG controller becomes active. The intent of this feature is to allow the JTAG interface to be directly controlled by the data bus of an embedded controller (hence the name Embedded Port Enable). The EPEN signal is used as a "device select" to prevent spurious programming and/or testing from occurring due to random bit patterns on the data bus. Figure 9 illustrates the block diagram for the ispJTAG™ interface.

The ispGDXV/VA devices provide IEEE1149.1a test capability and ISP programming through a standard Boundary Scan Test Access Port (TAP) interface.

The boundary scan circuitry on the ispGDXV/VA Family operates independently of the programmed pattern. This

allows customers using boundary scan test to have full test capability with only a single BSDL file.

The ispGDXV/VA devices are identified by the 32-bit JTAG IDCODE register. The device ID assignments are listed in Table 4.

Figure 10. Boundary Scan Register Circuit for I/O Pins

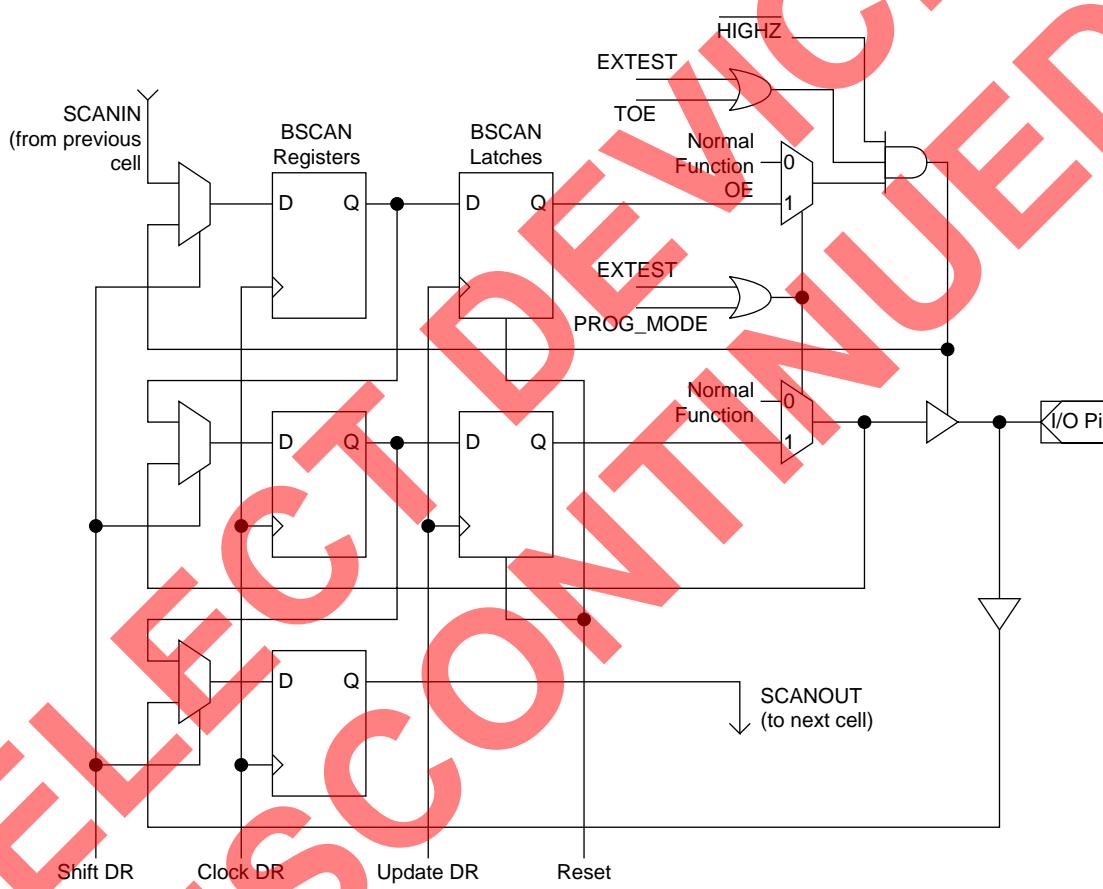


Table 3. I/O Shift Register Order

DEVICE	I/O SHIFT REGISTER ORDER
ispGDX160V/VA	TDI, TOE, Y2, Y3, RESET, Y1, Y0, I/O B20 .. B39, I/O C0 .. C39, I/O D0 .. D19, I/O B19 .. B0, I/O A39.. A0, I/O D39 .. D20, TDO

I/O Shift Reg Order/ispGDXVA

Table 4. ispGDX160V/VA Device ID Codes

DEVICE	32-BIT BOUNDARY SCAN ID CODE
ispGDX160V	0000, 0000, 0011, 0101, 0011, 0000, 0100, 0011
ispGDX160VA	0001, 0000, 0011, 0101, 0011, 0000, 0100, 0011

ID Code/GDX160V/VA

The ispJTAG programming is accomplished by executing Lattice private instructions under the Boundary Scan State Machine.

Details of the programming sequence are transparent to the user and are handled by Lattice ISP Daisy Chain

Download (ispDCD™), ispCODE 'C' routines or any third-party programmers. Contact Lattice Technical Support to obtain more detailed programming information.

Figure 11. Boundary Scan Register Circuit for Input-Only Pins

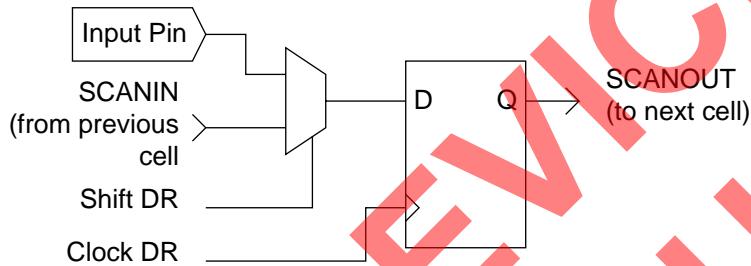


Figure 12. Boundary Scan State Machine

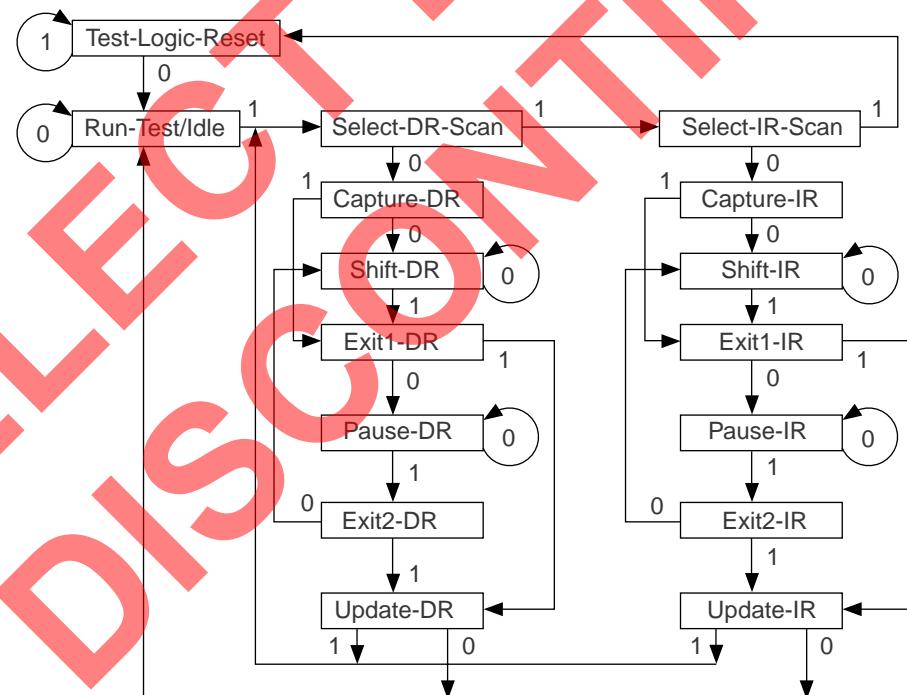
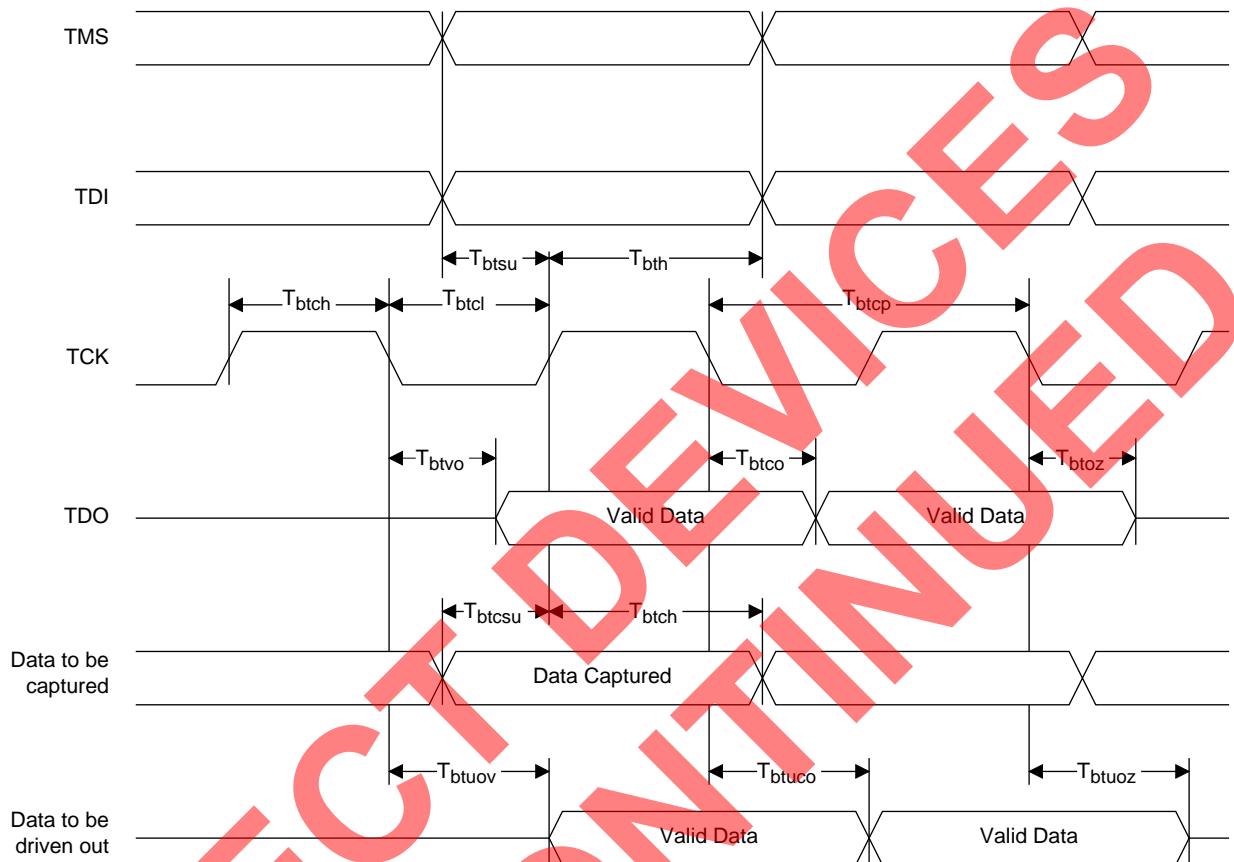


Figure 13. Boundary Scan Waveforms and Timing Specifications



Symbol	Parameter	Min	Max	Units
t_{btcp}	TCK [BSCAN test] clock pulse width	100	—	ns
t_{btch}	TCK [BSCAN test] pulse width high	50	—	ns
t_{btcl}	TCK [BSCAN test] pulse width low	50	—	ns
t_{btcsu}	TCK [BSCAN test] setup time	20	—	ns
t_{bth}	TCK [BSCAN test] hold time	25	—	ns
t_{rf}	TCK [BSCAN test] rise and fall time	50	—	mV/ns
t_{btcu}	TAP controller falling edge of clock to valid output	—	25	ns
t_{btco}	TAP controller falling edge of clock to data output disable	—	25	ns
t_{btvo}	TAP controller falling edge of clock to data output enable	—	25	ns
t_{btcpsu}	BSCAN test Capture register setup time	20	—	ns
t_{btcph}	BSCAN test Capture register hold time	25	—	ns
t_{btuco}	BSCAN test Update reg, falling edge of clock to valid output	—	50	ns
t_{btuo}	BSCAN test Update reg, falling edge of clock to output disable	—	50	ns
t_{btuov}	BSCAN test Update reg, falling edge of clock to output enable	—	50	ns

Signal Name	Description
I/O	Input/Output Pins – These are the general purpose bidirectional data pins. When used as outputs, each may be independently latched, registered or tristated. They can also each assume one other control function (OE, CLK/CLKEN, and MUXsel as described in the text).
TOE	Test Output Enable Pin – This pin tristates all I/P pins when a logic low is driven.
RESET	Active LOW Input Pin – Resets all I/O register outputs when LOW.
Yx/CLKENx	Input Pins –These can be either Global Clocks or Clock Enables.
EPEN	Input Pin – JTAG TAP Controller Enable Pin. When high, JTAG operation is enabled. When low, JTAG TAP controller is driven to reset.
TDI	Input Pin – Serial data input during ISP programming or Boundary Scan mode.
TCK	Input Pin – Serial data clock during ISP programming or Boundary Scan mode.
TMS	Input Pin – Control input during ISP programming or Boundary Scan mode.
TDO	Output Pin – Serial data output during ISP programming or Boundary Scan mode.
GND	Ground (GND)
VCC	Vcc – Supply voltage (3.3V).
VCCIO ²	Input – This pin is used if optional 2.5V output is to be used. Every I/O can independently select either 3.3V or the optional voltage as its output level. If the optional output voltage is not required, this pin must be connected to the VCC supply. Programmable pull-up resistors and bus-hold latches only draw current from this supply.
NC ¹	No Connect.

1. NC pins are not to be connected to any active signals, VCC or GND.

2. "VA" version only.

SELECT DISCONTINUED

Signal	208-Pin PQFP	208-Ball fpBGA	272-Ball BGA
TOE	178	D9	A12
RESET	185	A8	D10
Y0/CLKEN0	75	N8	V10
Y1/CLKEN1	76	R8	Y10
Y2/CLKEN2	180	B9	C11
Y3/CLKEN3	181	C9	A11
EPEN	183	A9	B10
TDI	81	P9	Y12
TCK	80	T9	U11
TMS	79	T8	V11
TDO	78	P8	W11
GND	6, 15, 25, 35, 44, 54, 63, 77, 91, 100, 110, 119, 129, 139, 148, 159, 168, 182, 195, 204	D4, D13, G7, G8, G9, G10, H7, H8, H9, H10, J7, J8, J9, J10, K7, K8, K9, K10, N4, N13	A1, D4, D8, D13, D17, H4, H17, J9, J10, J11, J12, K9, K10, K11, K12, L9, L10, L11, L12, M9, M10, M11, M12, N4, N17, U4, U8, U13, U17
VCC	1, 17, 33, 49, 65, 89, 105, 121, 137, 153, 156 ¹ , 170, 184, 193	E13 ¹ , F4, F13, L4, L13, M4, M13, N5, N11, N12, D5, D6, D12, E4	C18 ¹ , D6, D11, D15, F4, F17, K4, L17, R4, R17, U6, U10, U15
VCCIO	156 ¹	E13 ¹	C18 ¹
NC	73, 74, 179	A10, P7, T7	A2, A6, A7, A10, A15, A19, A20, B1, B2, B4, B11, B14, B18, B19, B20, C2, C3, C10, D2, D3, D16, E2, E17, E19, H1, H3, H18, H20, K20, L1, N1, N3, N18, N20, T2, T4, T19, U5, U18, U19, V3, V14, V18, V19, W1, W2, W3, W7, W10, W14, W19, W20, Y1, Y2, Y6, Y9, Y11, Y18, Y20

1. VCC on ispGDX160V, VCCIO on ispGDX160VA.

ispGDX160V/VA 272-Ball BGA Signal Diagram

ispGDX160V/VA
Bottom View

	20	19	18	17	16	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	
A	NC ¹	NC ¹	I/O D4	I/O D5	I/O D8	NC ¹	I/O D13	I/O D16	TOE	Y3/ CLKEN3	NC ¹	I/O D20	I/O D24	NC ¹	NC ¹	I/O D30	I/O D34	I/O D36	NC ¹	GND	
B	NC ¹	NC ¹	NC ¹	I/O D2	I/O D7	I/O D11	NC ¹	I/O D15	I/O D19	NC ¹	EPEN	I/O D21	I/O D25	I/O D27	I/O D29	I/O D33	NC ¹	I/O D39	NC ¹	NC ¹	
C	I/O C39	I/O D1	VCCIO	VCC ²	I/O D3	I/O D6	I/O D9	I/O D12	I/O D14	I/O D18	Y2/ CLKEN2	NC ¹	I/O D22	I/O D26	I/O D28	I/O D32	I/O D35	I/O D38	NC ¹	NC ¹	I/O A1
D	I/O C36	I/O C38	I/O D0	GND	NC ¹	VCC	I/O D10	GND	I/O D17	VCC	RESET	I/O D23	GND	I/O D31	VCC	I/O D37	GND	NC ¹	NC ¹	I/O A2	
E	I/O C33	NC ¹	I/O C37	NC ¹													I/O A0	I/O A3	NC ¹	I/O A4	
F	I/O C30	I/O C32	I/O C35	VCC													VCC	I/O A5	I/O A7	I/O A8	
G	I/O C28	I/O C29	I/O C31	I/O C34													I/O A6	I/O A9	I/O A10	I/O A11	
H	NC ¹	I/O C27	NC ¹	GND													GND	NC ¹	I/O A12	NC ¹	
J	I/O C23	I/O C24	I/O C25	I/O C26													I/O A13	I/O A14	I/O A15	I/O A16	
K	NC ¹	I/O C20	I/O C21	I/O C22													VCC	I/O A18	I/O A17	I/O A19	
L	I/O C19	I/O C17	I/O C18	VCC													I/O A22	I/O A21	I/O A20	NC ¹	
M	I/O C16	I/O C15	I/O C14	I/O C13													I/O A26	I/O A25	I/O A24	I/O A23	
N	NC ¹	I/O C12	NC ¹	GND													GND	NC ¹	I/O A27	NC ¹	
P	I/O C11	I/O C10	I/O C9	I/O C6													I/O A34	I/O A31	I/O A29	I/O A28	
R	I/O C8	I/O C7	I/O C5	VCC													VCC	I/O A35	I/O A32	I/O A30	
T	I/O C4	NC ¹	I/O C3	I/O C0													NC ¹	I/O A37	NC ¹	I/O A33	
U	I/O C2	NC ¹	NC ¹	GND	I/O B36	VCC	I/O B30	GND	I/O B22	TCK	VCC	I/O B17	GND	I/O B10	VCC	NC ¹	GND	I/O B0	I/O A38	I/O A36	
V	I/O C1	NC ¹	NC ¹	I/O B37	I/O B34	I/O B31	NC ¹	I/O B25	I/O B21	TMS	Y0/ CLKEN0	I/O B18	I/O B14	I/O B12	I/O B9	I/O B6	I/O B3	NC ¹	I/O B1	I/O A39	
W	NC ¹	NC ¹	I/O B38	I/O B35	I/O B32	I/O B28	NC ¹	I/O B24	I/O B20	TDO	NC ¹	I/O B19	I/O B15	NC ¹	I/O B11	I/O B7	I/O B2	NC ¹	NC ¹	NC ¹	
Y	NC ¹	I/O B39	NC ¹	I/O B33	I/O B29	I/O B27	I/O B26	I/O B23	TDI	NC ¹	Y1/ CLKEN1	NC ¹	I/O B16	I/O B13	NC ¹	I/O B8	I/O B5	I/O B4	NC ¹	NC ¹	

1. NCs are not to be connected to any active signals, Vcc or GND.

2. VCCIO on ispGDX160VA. VCC on ispGDX160V.

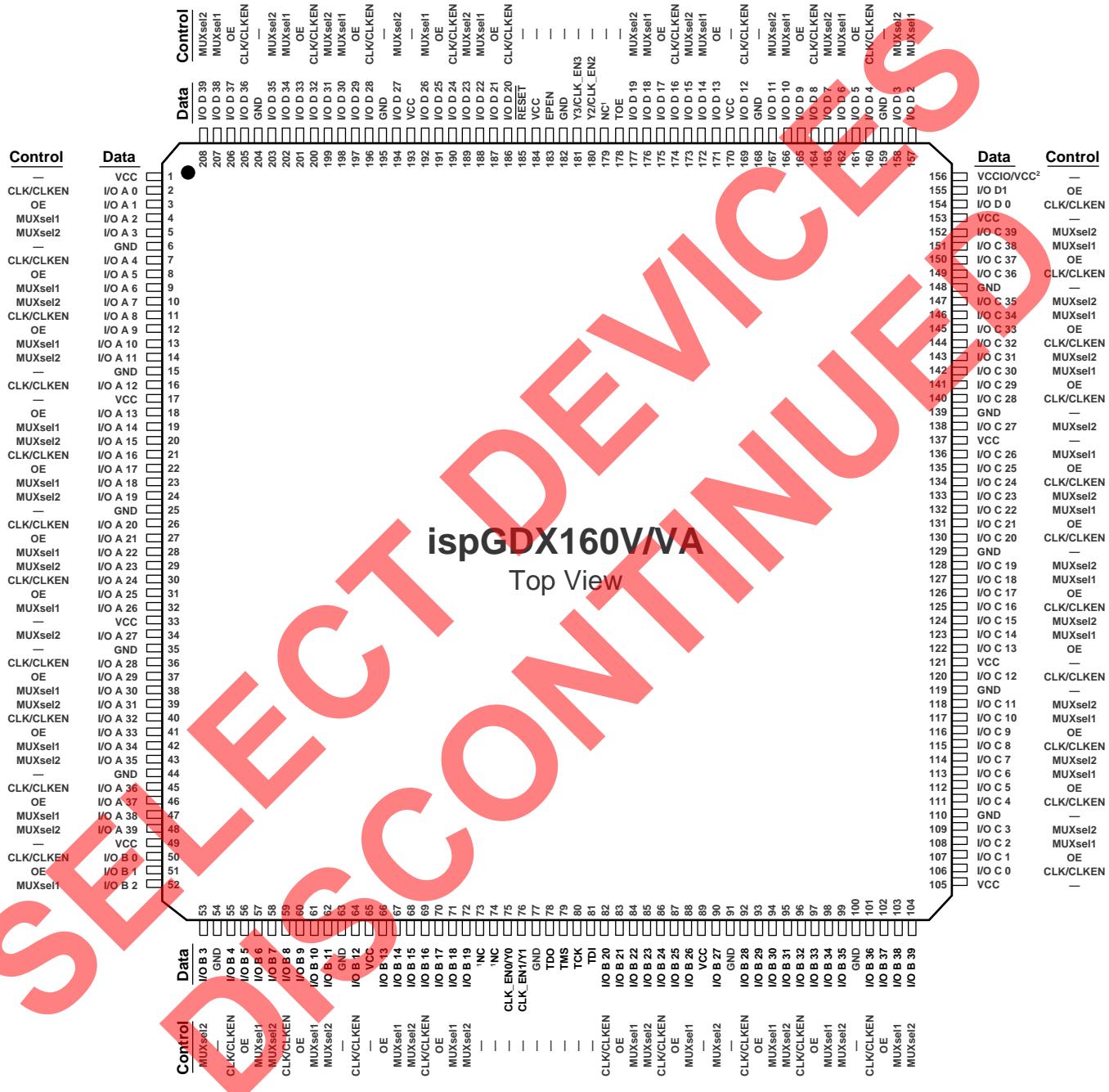
ispGDX160V/VA 208-Ball fpBGA Signal Diagram

	16	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	
A	I/O D1	I/O D3	I/O D6	I/O D9	I/O D13	I/O D17	NC ¹	EPEN	RESET	I/O D23	I/O D27	I/O D30	I/O D33	I/O D36	I/O D39	I/O A3	A
B	I/O D0	I/O D2	I/O D5	I/O D8	I/O D11	I/O D15	I/O D18	Y2/ CLKEN2	I/O D21	I/O D25	I/O D29	I/O D32	I/O D34	I/O D38	I/O A0	I/O A1	B
C	I/O C36	I/O C39	I/O D4	I/O D7	I/O D10	I/O D14	I/O D19	Y3/ CLKEN3	I/O D20	I/O D24	I/O D28	I/O D31	I/O D35	I/O D37	I/O A2	I/O A4	C
D	I/O C35	I/O C37	I/O C38	GND	VCC	I/O D12	I/O D16	TOE	I/O D22	I/O D26	VCC	VCC	GND	I/O A5	I/O A6	I/O A7	D
E	I/O C32	I/O C34	I/O C33	VCCIO/ VCC ²									VCC	I/O A8	I/O A9	I/O A10	E
F	I/O C29	I/O C31	I/O C30	VCC									VCC	I/O A11	I/O A12	I/O A13	F
G	I/O C25	I/O C27	I/O C26	I/O C28									I/O A14	I/O A16	I/O A15	I/O A17	G
H	I/O C22	I/O C23	I/O C21	I/O C24									I/O A18	I/O A20	I/O A19	I/O A21	H
J	I/O C20	I/O C18	I/O C19	I/O C17									I/O A25	I/O A23	I/O A24	I/O A22	J
K	I/O C16	I/O C14	I/O C15	I/O C13									I/O A29	I/O A27	I/O A28	I/O A26	K
L	I/O C12	I/O C10	I/O C11	VCC									VCC	I/O A32	I/O A31	I/O A30	L
M	I/O C9	I/O C8	I/O C7	VCC									VCC	I/O A35	I/O A34	I/O A33	M
N	I/O C6	I/O C5	I/O C3	GND	VCC	VCC	I/O B25	I/O B21	Y0/ CLKEN0	I/O B18	I/O B13	VCC	GND	I/O A38	I/O A37	I/O A36	N
P	I/O C4	I/O C1	I/O C0	I/O B35	I/O B30	I/O B27	I/O B23	TDI	TDO	NC ¹	I/O B16	I/O B11	I/O B7	I/O B4	I/O B0	I/O A39	P
R	I/O C2	I/O B39	I/O B36	I/O B33	I/O B31	I/O B28	I/O B24	I/O B20	Y1/ CLKEN1	I/O B19	I/O B15	I/O B12	I/O B9	I/O B6	I/O B2	I/O B1	R
T	I/O B38	I/O B37	I/O B34	I/O B32	I/O B29	I/O B26	I/O B22	TCK	TMS	NC ¹	I/O B17	I/O B14	I/O B10	I/O B8	I/O B5	I/O B3	T

1. NCs are not to be connected to any active signals, Vcc or GND.

2. VCCIO on ispGDX160VA. VCC on ispGDX160V.

ispGDX160V/VA 208-Pin PQFP Pinout Diagram



1. No Connect Pins (NC) are not to be connected to any active signal, Vcc or GND.
2. VCCIO on *ispGDX160VA*. VCC on *ispGDX160V*.

Device Family ispGDX XXXXX - X XXXXX X
 Device Number 160V
160VA
 Speed 3 = 3.5ns Tpd
5 = 5ns Tpd
7 = 7ns Tpd
9 = 9ns Tpd

Grade

Blank = Commercial

I = Industrial

Package

Q208 = 208-Pin PQFP

B208 = 208-Ball fpBGA

BN208 = Lead-Free 208-Ball fpBGA

B272 = 272-Ball BGA

0212/ispGDXVA

Conventional Packaging
COMMERCIAL

FAMILY	tpd (ns)	ORDERING NUMBER	PACKAGE
ispGDXVA	3.5	ispGDX160VA-3Q208	208-Pin PQFP
	3.5	ispGDX160VA-3B208	208-Ball fpBGA
	3.5	ispGDX160VA-3B272	272-Ball BGA
	5	ispGDX160VA-5Q208	208-Pin PQFP
	5	ispGDX160VA-5B208	208-Ball fpBGA
	5	ispGDX160VA-5B272	272-Ball BGA
	7	ispGDX160VA-7Q208	208-Pin PQFP
	7	ispGDX160VA-7B208	208-Ball fpBGA
	7	ispGDX160VA-7B272	272-Ball BGA
ispGDXV*	5	ispGDX160V-5Q208	208-Pin PQFP
	5	ispGDX160V-5B208	208-Ball fpBGA
	5	ispGDX160V-5B272	272-Ball BGA
	7	ispGDX160V-7Q208	208-Pin PQFP
	7	ispGDX160V-7B208	208-Ball fpBGA
	7	ispGDX160V-7B272	272-Ball BGA

*Use ispGDX160VA for new designs.

Note: The ispGDX160VA devices are dual-marked with both Commercial and Industrial grades. The Industrial speed grade is slower, e.g. ispGDX160VA-3B208-5I.

Table 2-0041A/ispGDXV/A

Conventional Packaging (Cont.)

INDUSTRIAL

FAMILY	tpd (ns)	ORDERING NUMBER	PACKAGE
ispGDXVA	5	ispGDX160VA-5Q208I	208-Pin PQFP
	5	ispGDX160VA-5B208I	208-Ball fpBGA
	5	ispGDX160VA-5B272I	272-Ball BGA
	7	ispGDX160VA-7Q208I	208-Pin PQFP
	7	ispGDX160VA-7B208I	208-Ball fpBGA
	7	ispGDX160VA-7B272I	272-Ball BGA
	9	ispGDX160VA-9Q208I	208-Pin PQFP
	9	ispGDX160VA-9B208I	208-Ball fpBGA
	9	ispGDX160VA-9B272I	272-Ball BGA
ispGDXV*	7	ispGDX160V-7Q208I	208-Pin PQFP

*Use ispGDX160VA for new designs.

Note: The ispGDX160VA devices are dual-marked with both Commercial and Industrial grades. The Industrial speed grade is slower, e.g. ispGDX160VA-3B208-5I.

Table 2-0041C/ispGDXV

Lead-Free Packaging

COMMERCIAL

FAMILY	tpd (ns)	ORDERING NUMBER	PACKAGE
ispGDXVA	3.5	ispGDX160VA-3BN208	Lead-Free 208-Ball fpBGA
	5	ispGDX160VA-5BN208	Lead-Free 208-Ball fpBGA
	7	ispGDX160VA-7BN208	Lead-Free 208-Ball fpBGA

INDUSTRIAL

FAMILY	tpd (ns)	ORDERING NUMBER	PACKAGE
ispGDXVA	5	ispGDX160VA-5BN208I	Lead-Free 208-Ball fpBGA
	7	ispGDX160VA-7BN208I	Lead-Free 208-Ball fpBGA
	9	ispGDX160VA-9BN208I	Lead-Free 208-Ball fpBGA

Note: The ispGDX160VA devices are dual-marked with both Commercial and Industrial grades. The Industrial speed grade is slower, e.g. ispGDX160VA-3B208-5I.